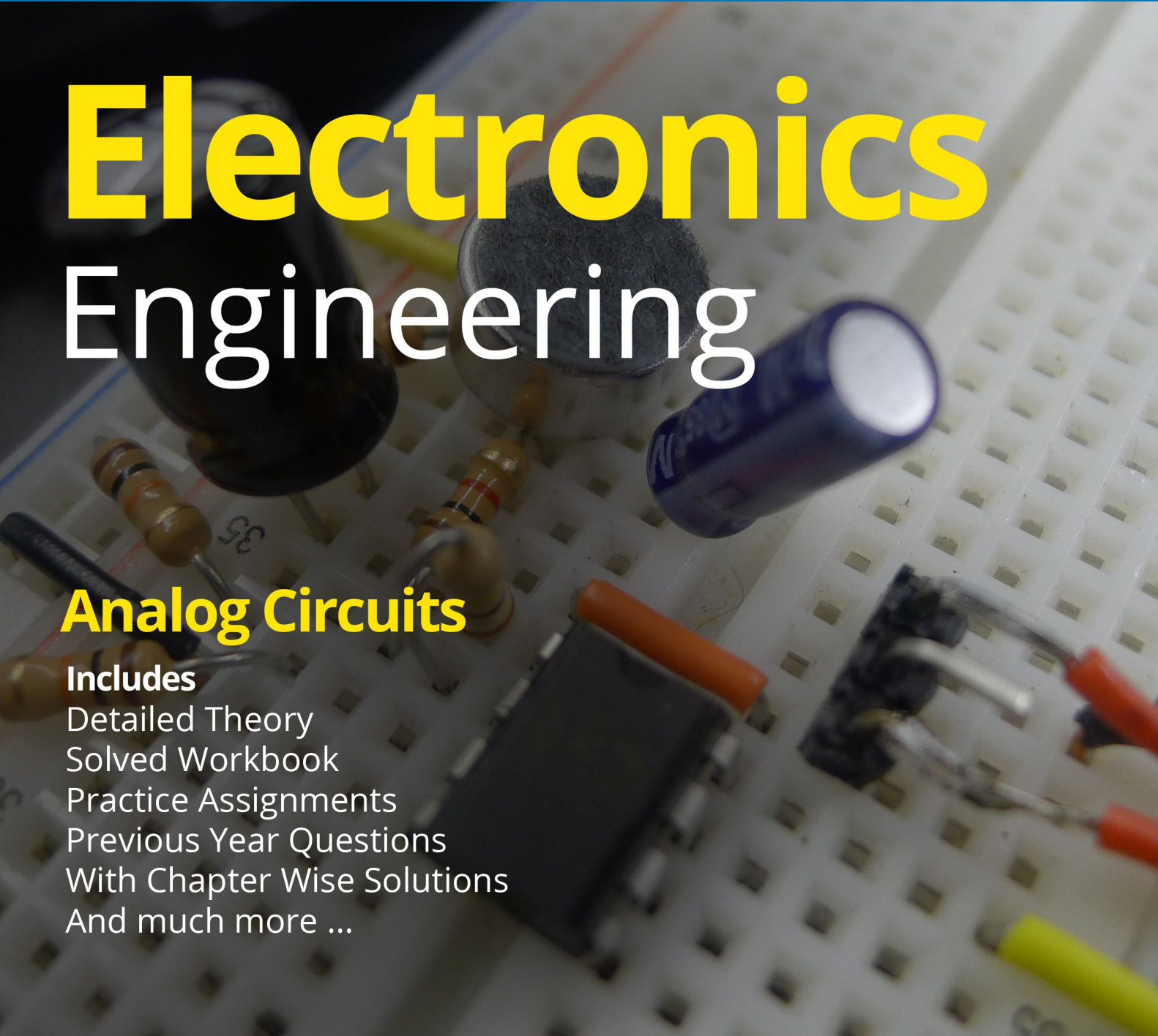


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CHAPTER - 1

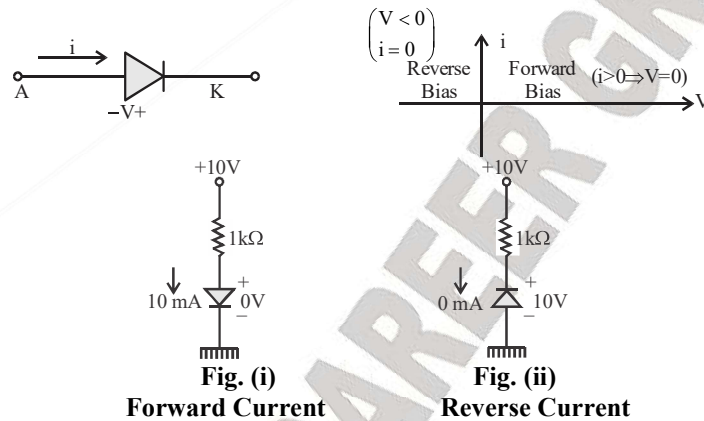
DIODE CIRCUITS

1.1 INTRODUCTION

The simplest and most fundamental non-linear circuit element is a diode. Just like a resistor, the diode has two terminals but the diode has a non-linear i-v characteristics.

1.1.1 Diode Circuits

DC analysis and models. The ideal diode may be considered the most fundamental non-linear circuit element.

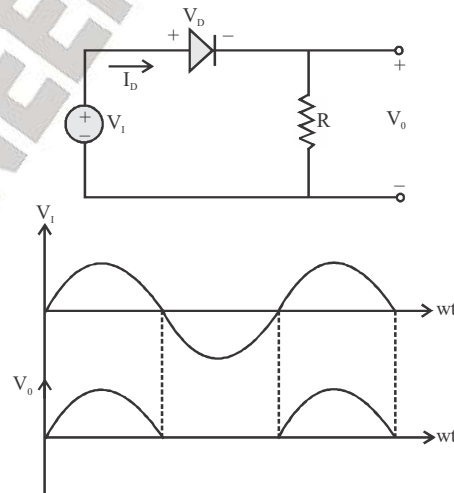


In above fig(i) the diode is conducting. Thus its voltage drop will be zero and the current through it will be determined by the +10V supply and the 1 k Ω resistor as 10 mA. In fig(ii) the diode is cut off and thus its current will be zero.

1.1.2 A Simple Applications

1.1.2.1 The Rectifier

The circuit consists of the series connection of a diode D and a resistor R.



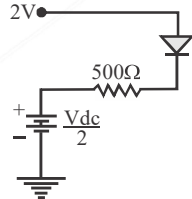
GATE QUESTIONS

1. An AC voltage source $V = 10 \sin(t)$ volts is applied to the following network. Assume that $R_1 = 3k\Omega$, $R_2 = 6k\Omega$ and $R_3 = 9k\Omega$ and that the diode is ideal.

Rms circuit I_{rms} (in mA) through the diode is _____

[GATE - 2017]

2. The silicon diode, shown in the figure, has a barrier potential of 0.7 V. There will be no forward current flow through the diode, if V_{dc} , in volt, is greater than



[GATE - 2017]

- (a) 0.7
- (b) 1.3
- (c) 1.8
- (d) 2.6

3. In the circuit shown below, V_s is a constant voltage source and I_L is a constant current load

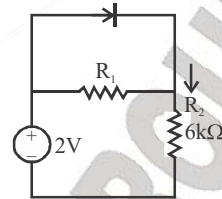


The value of I_L that maximizes the power absorbed by the constant current load is

[GATE - 2016]

- (a) $\frac{V_s}{4R}$
- (b) $\frac{V_s}{2R}$
- (c) $\frac{V_s}{R}$
- (d) ∞

4. Assume that the diode in the figure has $V_{on} = 0.7$ V, but is otherwise ideal.



The magnitude of the current i_2 (in mA) is equal to _____

[GATE - 2016]

5. The I-V characteristics of the zener diodes D1 and D2 are shown in figure 1. These diodes are used in the circuit given in figure II. If the supply voltage is varied from 0 to 100V, then breakdown occurs in

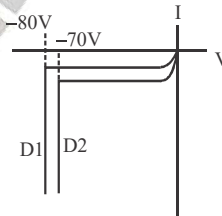


Figure I

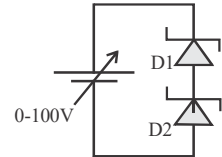


Figure II

[GATE - 2016]

- (a) D1 only
- (b) D2 only
- (c) both D1 and D2
- (d) none of D1 and D2

6. In the circuit shown, assume that the diodes D_1 and D_2 are ideal. The average value of voltage V_{ab} (in Volts), across terminals 'a' and 'b' is _____.

ESE OBJ QUESTIONS

1. In an L-section filter, a bleeder resistance connected across the load
[EE ESE - 2015]
- (a) Provides good regulation for all values of load
(b) Ensure lower PIV of the diodes
(c) Ensures lower values of capacitance in the filter
(d) Reduces ripple content
2. A schottky diode is
[EE ESE - 2015]
- (a) A majority carrier device
(b) A minority carrier device
(c) A fast recovery diode
(d) Both majority and minority carrier diode
3. Ripple - rejection ratio of voltage regulator is the ratio of
[EE ESE - 2015]
- (a) Output voltage to input ripple voltage
(b) Output power to input power of regulator
(c) Input power to output power of regulator
(d) Input ripple voltage to output ripple voltage
4. Which of the following is called 'hot carrier diode'?
[EE ESE - 2015]
- (a) PIN diode (b) LED
(c) Photo diode (d) Schottky diode
5. Compared to an ordinary semiconductor diode a Schottky diode has
[EE ESE - 2015]
- (a) Higher reverse saturation current and zero cut-in voltage
(b) Higher reverse saturation current and higher cut-in voltage
(c) Higher reverse saturation current and lower cut in voltage
(d) Lower reverse saturation current and lower cut-in voltage
6. A silicon diode is preferred to a germanium diode because of its
[EE ESE - 2015]
- (a) Higher reverse current
(b) Lower reverse current and higher reverse break down voltage
(c) Higher reverse current and lower reverse break down voltage
(d) None of the above
7. In a P-N junction diode under reverse bias, the magnitude of electric field is maximum at
[EE ESE - 2015]
- (a) The edge of the depletion region in the P side
(b) The edge of the depletion region on the N side
(c) The centre of the depletion region on the N side
(d) The P-N junction
8. A full wave rectifier uses 2 diodes. The internal resistance of each diode is 20Ω . The transformers RMS secondary voltage from centre tap to each end of secondary is 50V and the load resistance is 980Ω . Mean load current will be
[EC ESE - 2015]
- (a) 45A (b) 4.5A
(c) 45 mA (d) 45 μ A
9. The increase in value of β of transistor can cause the fixed bias circuit to
[EE ESE - 2014]
- (a) Shift from saturation region to active region
(b) Shift the operation from active mode to saturation mode
(c) Shift the operation from saturation mode to cut off mode
(d) Shift the operation from cut-off mode to active mode
10. As compared to an LED, an LCD has the distinct advantage of

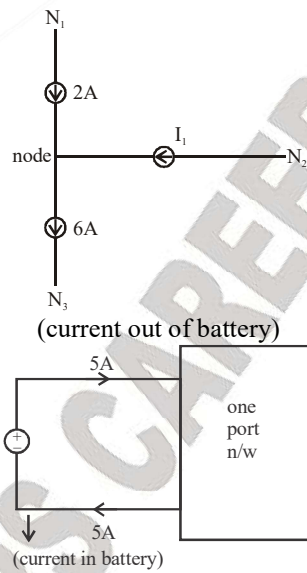
CHAPTER - 2
BJT BIASING AND SMALL SIGNAL ANALYSIS

2.1 BASIC OF NETWORK

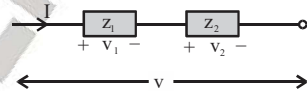
1. KCL
2. KVL
3. Nodal Analysis

Example.

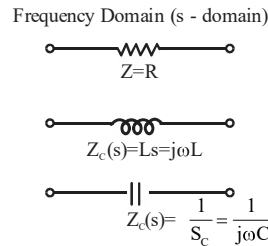
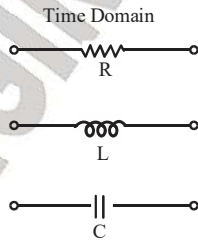
$I_1 + 2 = 6$



1. Voltage Divider Rule



$$v_1 = \frac{v \times Z_1}{Z_1 + Z_2}$$



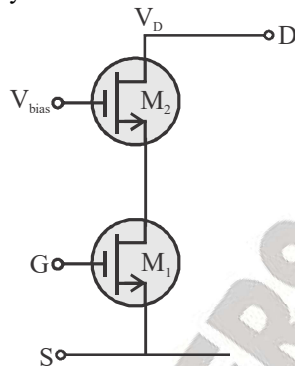
GATE QUESTIONS

1. Two identical nMOS transistors M_1 and M_2 are connected as shown below. The circuit is used as an amplifier with the input connected between G and S terminals and the output taken between D and S terminals, V_{bias} and V_D are so adjusted that both transistors

are in saturation. The transconductance of this combination is defined as $g_m = \frac{\partial i_D}{\partial v_{GS}}$ while

the output resistance is $r_o = \frac{\partial v_{DS}}{\partial i_D}$, where i_D is

the current flowing into the drain of M_2 . Let g_{m1} , g_{m2} be the transconductances and r_{o1} , r_{o2} be the output resistance of transistors M_1 and M_2 , respectively

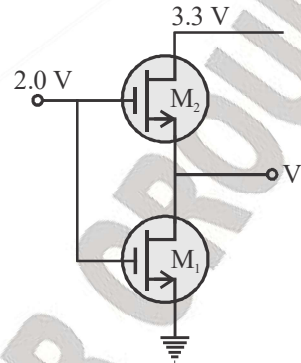


Which of the following statements about estimates for g_m and r_o is correct?

[GATE - 2018]

- (a) $g_m \approx g_{m1} \cdot g_{m2} \cdot r_{o2}$ and $r_o \approx r_{o1} + r_{o2}$
- (b) $g_m \approx g_{m1} + g_{m2}$ and $r_o \approx r_{o1} + r_{o2}$
- (c) $g_m \approx g_{m1}$ and $r_o \approx r_{o1} \cdot g_{m2} \cdot r_{o2}$
- (d) $g_m \approx g_{m1}$ and $r_o \approx r_{o2}$

2. In the circuit shown below, the (W/L) value for M_2 is twice that for M_1 . The two nMOS transistors are otherwise identical. The threshold voltage V_T for both transistors is 1.0 V. Note that V_{GS} for M_2 must be > 1.0 V



Current through the nMOS transistors can be modeled as

$$I_{DS} = \mu C_{ox} \left(\frac{W}{L} \right) \left((V_{GS} - V_T) V_{DS} - \frac{1}{2} V_{DS}^2 \right) \text{ for } V_{DS} \leq V_{GS} - V_T$$

$$I_{DS} = \mu C_{ox} \left(\frac{W}{L} \right) (V_{GS} - V_T)^2 / 2 \text{ for } V_{DS} \geq V_{GS} - V_T$$

The voltage (in volts, accurate to two decimal places) at V_x is _____.

[GATE - 2018]

3. An npn bipolar junction transistor (BJT) is operating in the active region. If the reverse bias across the base-collector junction is increased, then

[GATE - 2017]

- (a) The effective base width increase and common-emitter current gain increases
- (b) The effective base width increase and common-emitter current gain decreases
- (c) The effective base width decrease and common-emitter current gain increases
- (d) The effective base width decrease and common-emitter current gain decreases

4. Consider the circuit shown in figure. Assume base to emitter voltage $V_{BE} = 0.8$ V and common base current gain (α) of transistor is unity

ESE OBJ QUESTIONS

1. A transistor is connected in CE configuration with $V_{CC} = 10V$. The voltage drop across the 600Ω resistor in the collector circuit is $0.6V$. If $\alpha = 0.98$, the base current is nearly

[EC ESE - 2018]

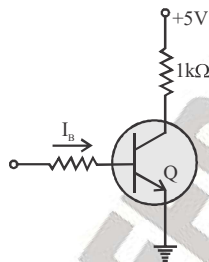
- (a) 6.12 mA (b) 2.08 mA
(c) 0.98 mA (d) 0.02 mA

2. A single stage amplifier has a voltage gain of 100. The load connected to the collector is 500Ω and its input impedance is $1k\Omega$. Two such stages are connected in cascade through an RC coupling. The overall gain is

[EC ESE - 2016]

- (a) 10000 (b) 6666.66
(c) 5000 (d) 1666.66

3. Assuming $V_{CE}(\text{Sat}) = 0.3V$ for a silicon transistor at ambient temperature of $25^\circ C$ and $h_{FE} = 50$, the minimum base current I_B required to drive the transistor into saturation for the circuit shown is



[EC ESE - 2016]

- (a) $64\mu A$ (b) $78\mu A$
(c) $94\mu A$ (d) $140\mu A$

4. Which of the following regions of operations are mainly responsible for heating of the transistor under switching operation ?

1. Saturations region
2. Cut off region
3. Transition from saturation to cut off
4. Transition from cut – off to saturation select the correct answer using the codes given below:

[EC ESE - 2016]

- (a) 1, 2 and 4 only (b) 1, 3 and 4 only
(c) 2 and 3 only (d) 1 and 3 only

5. Consider the following statements regarding linear power supply.

1. It requires low frequency transformer.
2. It requires high frequency transformer.
3. The transistor works in active region. Which of the above statements is/are correct?

[EC ESE - 2016]

- (a) 1 only (b) 2 and 3 only
(c) 1 and 3 only (d) 3 only

6. The most commonly used transistor configuration for use as a switching device is

[EC ESE - 2016]

- (a) Common - base configuration
(b) Common - collector configuration
(c) Collector - emitter shorted configuration
(d) Common - emitter configuration

7. The value of h_{FE} (the hybrid parameters) of a Common - Emitter (CE) connection of a bipolar Junction Transistor (BJT) is given as 250. What is the value of α_{dc} (ratio of collector current to emitter current), for this BJT ?

[EC ESE - 2016]

- (a) 0.436 (b) 0.656
(c) 0.874 (d) 0.996

8. The h-parameters of a CE amplifier feeding a load of $10k\Omega$ are $h_{ie} = 1k\Omega$, $h_{fe} = 50$, $h_{re} = 0$, and $1/h_{oe} = 40k\Omega$. The voltage gain would be

[EC ESE - 2015]

- (a) -40 (b) -100
(c) -400 (d) -500

9. Consider the following statements pertaining to frequency response of RC coupled amplifier.

1. Coupling capacitance affects high frequency response
2. Bypass capacitance affects high frequency response

CHAPTER - 3

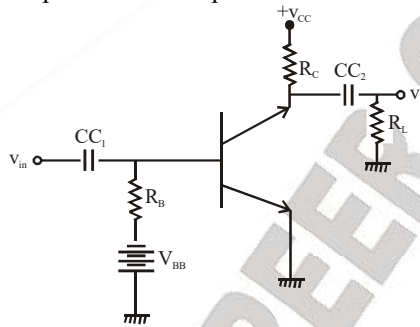
FREQUENCY RESPONSE

3.1 CAPACITORS

There are three types of capacitors

1. Coupling Capacitor
2. Emitter Capacitor
3. Junction Capacitance/ Internal Capacitance

To determine the gain of amplifier with respect to itself frequency we need to do frequency analysis of amplifier in which response of the amplifier is studied over the range of frequency.



$$\text{Slope of DC Load Line} = -\frac{1}{R_C}$$

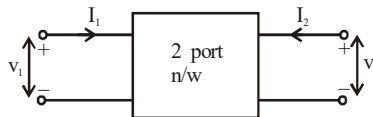
$$\text{Slope of AC Load Line, } m = -\frac{1}{R'_L} = -\left(\frac{1}{R_C} + \frac{1}{R_L}\right)$$

$$\therefore R'_L = \frac{1}{\left(\frac{1}{R_C} + \frac{1}{R_L}\right)}$$



The slope of AC line is greater as compared to slope of DC line.

3.2 H-PARAMETER ANALYSIS OF BJT



$$V_1 = f(I, V_2)$$

$$I_2 = f(I, V_2)$$

$$V_1 = h_{11} I_1 + h_{12} V_2$$

$$I_2 = h_{21} I_1 + h_{22} V_2$$

ESE OBJ QUESTIONS

1. The gain of a bipolar transistor drops at high frequencies. This is due to

[EC ESE-2018]

- (a) Coupling and bypass capacitors
- (b) Early effect
- (c) Inter – electrode transistor capacitances
- (d) The fact that reactance becomes high

2. The n-p-n transistor made of silicon has a DC base bias voltage 15 V and an input base resistor 150 K Ω . Then the value of the base current into the transistor is

[EC ESE-2017]

- (a) 0.953 μ A
- (b) 9.53 μ A
- (c) 95.3 μ A
- (d) 953 μ A

3. The capacitance of a full wave rectifier, with 60hz input signal, peak output voltage $V_p = 10$ v, load resistance $R = 10$ k Ω and input ripple voltage $V_r = 0.2$ V, is

[EC ESE - 2016]

- (a) 22.7 μ F
- (b) 33.3 μ F
- (c) 41.7 μ F
- (d) 83.4 μ F

4. A full wave rectifier connected to the output terminals of the mains transformer produces an RMS voltage of 18V across the secondary. The no - load voltage across the secondary of the transformer is

[EC ESE - 2016]

- (a) 1.62 V
- (b) 16.2 V
- (c) 61.2 V
- (d) 6.12 V

5. A power supply uses bridge rectifier with capacitor input filter. If one of the diodes is defective, then

1. The dc load voltage will be lower than its expected value.
 2. Ripple frequency will be lower than its expected value.
 3. The surge current will increase manifold
- Which of the above statements are correct?

[EC ESE - 2015]

- (a) 1 and 2 only
- (b) 1 and 3 only
- (c) 2 and 3 only
- (d) 1, 2 and 3

6. In an L-section filter, a bleeder resistance is connected across the load to

[EC ESE - 2015]

- (a) Provide good regulation for all values of load
- (b) Ensure lower PIV of the diodes
- (c) Ensure lower values of capacitance in the filter
- (d) Reduce ripple content

7. In a voltage regulator, zener diode is

1. connected in series with filter output
2. Forward biased
3. Connected in parallel with filter output
4. Reversed biased

Which of the above are correct

[EC ESE - 2015]

- (a) 1 and 2
- (b) 3 and 4
- (c) 1 and 4
- (d) 2 and 3

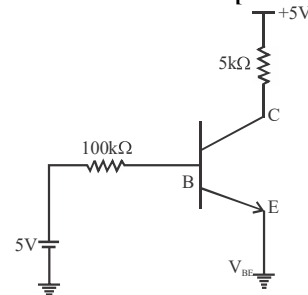
8. With the increase of reverse bias in a p-n diode, the reverse current

[EC ESE - 2013]

- (a) Decreases
- (b) Increases
- (c) Remains constant
- (d) May increase or decrease depending upon doping

9. The transistor as shown in the circuit is operating in:

[EC ESE - 2013]



- (a) Cut - off region
- (b) Saturation region
- (c) Active region
- (d) Either in active or saturation region

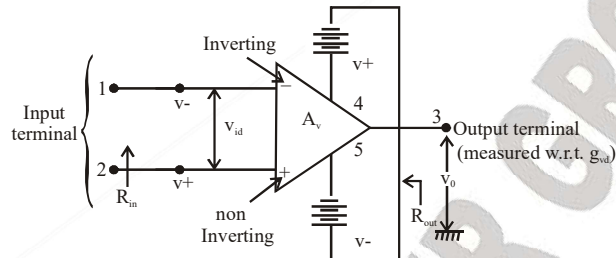
CHAPTER - 4

OPERATIONAL AMPLIFIER AND APPLICATIONS

4.1 INTRODUCTION

Operational amplifier is a d.c. coupled high gain voltage amplifier.

Operational amplifier is available in IC form and it can be obtained in 7 pin ICs or more than 14 pin IC's and many more.

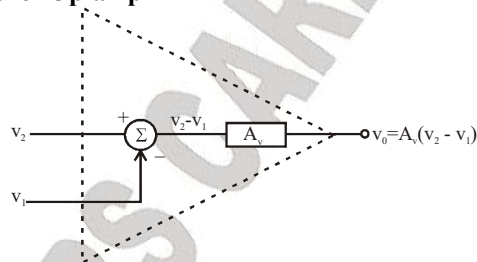


v^+ and v^- are d.c. supplies

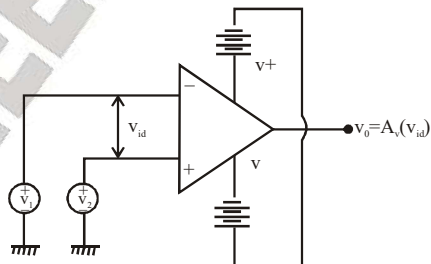
v^+ and v^- are the two dc power supplies which are necessary for its working.

$$v_{id} = v_+ - v_-$$

4.1.1 Mathematical Model of Op-amp



Op-amp is design to sense the difference between voltage signal to applied between its two input signal.



v_1 and v_2 are the voltage applied w.r.t ground.

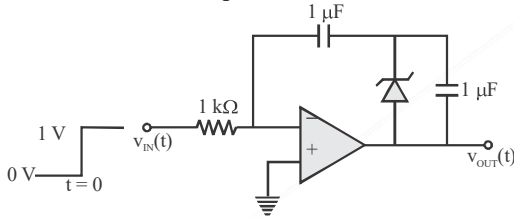
$$\text{If } v_1 = v_2 = v \therefore v_o = A_v [v - v] = 0.$$

If we provide same input at both end then the output will be zero ideally.

Hence in ideal op-amp common voltage should be zero.

GATE QUESTIONS

1. In the circuit shown below, the op-amp is ideal and Zener voltage of the diode is 2.5 volts. At the input, unit step voltage is applied i.e. $v_{IN}(t) = u(t)$ volts. Also at $t = 0$, the voltage across each of the capacitors is zero

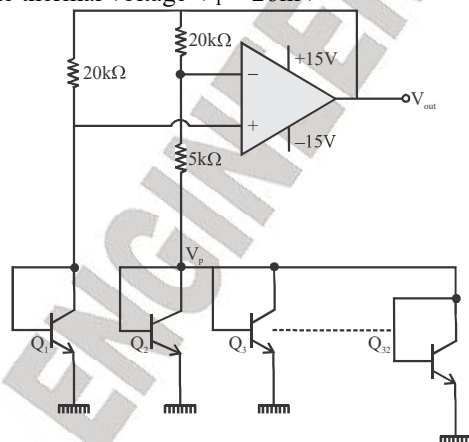


The time t , in milliseconds, at which the output voltage v_{OUT} crosses -10 V is

- (a) 2.5 (b) 5
(c) 7.5 (d) 10

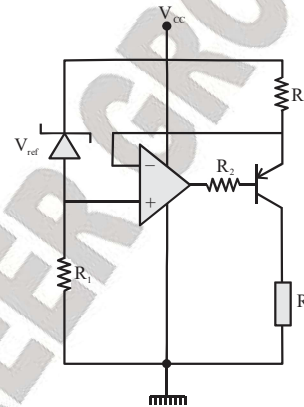
[GATE - 2018]

2. In the voltage reference circuit shown in the figure, the op-amp is ideal and transistors Q_1, Q_2, \dots, Q_{32} are identical in all respects and have infinitely large values of common-emitter current gain (β). The collector current (I_C) of the transistors is related to their base emitter voltage (V_{BE}) by the relation $I_C = I_s \exp(V_{BE}/V_T)$; where I_s is the saturation current. Assume that the voltage V_p shown in the figure is $0.7V$ and the thermal voltage $V_T = 26mV$



The output voltage V_{out} (in volts) is _____

3. Consider the constant current source shown in the figure below. Let β represent the current gain of the transistor

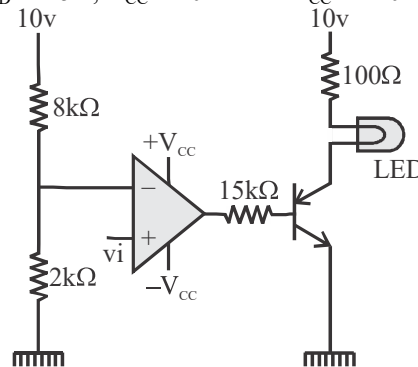


The load current I_0 through R_L is

- (a) $I_0 = \left(\frac{\beta+1}{\beta}\right) \frac{V_{ref}}{R}$ (b) $I_0 = \left(\frac{\beta}{\beta+1}\right) \frac{V_{ref}}{R}$
(c) $I_0 = \left(\frac{\beta+1}{\beta}\right) \frac{V_{ref}}{2R}$ (d) $I_0 = \left(\frac{\beta}{\beta+1}\right) \frac{V_{ref}}{2R}$

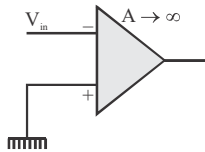
[GATE - 2017]

4. The following signal V_i of peak voltage $8V$ is applied to the non-inverting terminal of an ideal Opamp. The transistor has $V_{BE} = 0.7V, \beta = 100; V_{LED} = 1.5V, V_{CC} = 10V$ and $-V_{CC} = -10V$.



ESE OBJ QUESTIONS

1. If the input (V_{in}) to the circuit is a sine wave, the output will be



[EE ESE - 2017]

- (a) Half-wave rectified sine wave
- (b) Full-wave rectified sine wave
- (c) Triangular wave
- (d) Square wave

2. If an input impedance of op-amp is finite, then which one of the following statements related to virtual ground is correct?

[EE ESE - 2017]

- (a) Virtual ground condition may exist
- (b) Virtual ground condition cannot exist
- (c) In case of op-amp, virtual ground condition always exists
- (d) Cannot make a valid declaration

3. Hysteresis is desirable in a Schmidt-trigger because

[EE ESE - 2017]

- (a) Energy is to be stored/discharged in parasitic capacitances
- (b) Effects of temperature variations would be compensated
- (c) Devices in the circuit should be allowed time for saturating and de-saturation
- (d) It would prevent noise from causing false triggering

4. An Op-Amp can be connected to provide

- 1. Voltage controlled current source
- 2. Current controlled voltage source
- 3. Current controlled current source which of the above statements are correct?

[EE ESE - 2016]

- (a) 1 and 2 only
- (b) 1 and 3 only
- (c) 2 and 3 only
- (d) 1, 2 and 3

5. In an Op-Amp, if the feedback voltage is reduced by connecting a voltage divider at the output. Which of the following will happen?

- 1. Input impedance increases
- 2. Output impedance reduces
- 3. Overall gain increases

Which of the above statements is/are correct?

[EE ESE - 2016]

- (a) 1 only
- (b) 2 only
- (c) 3 only
- (d) 1, 2 and 3

6. The transient response rise time (unity gain) of an Op-Amp is $0.05 \mu s$. The small signal bandwidth is

[EE ESE - 2016]

- (a) 7 kHz
- (b) 20 kHz
- (c) 7 MHz
- (d) 20MHz

7. A negative feedback of $\beta = 2.5 \times 10^{-3}$ is applied to an amplifier of open - loop gain 1000. What is the change in overall gain of the feedback amplifier, if the gain of the internal amplifier is reduced by 20%?

[EE ESE - 2016]

- (a) 295.7
- (b) 286.7
- (c) 275.7
- (d) 266.7

8. **Statement (I):** An ideal op- amp should have infinite bandwidth

Statement II: An ideal op amp should have infinite input resistance and zero output resistance

[EE ESE - 2015]

Codes:

- (a) Both Statement (I) and Statement (II) are individually true and Statement (II) is the correct explanation of Statement (I)
- (b) Both statement (I) and Statement (II) are individually true but statement (II) is not the correct explanation of statement (I)
- (c) Statement (I) is true but statement (II) is false
- (d) Statement(I) is false but statement (II) is true

CHAPTER - 5

FEEDBACK AMPLIFIER AND OSCILLATOR

5.1 FEEDBACK ARE OF TWO TYPES

1. Regenerative feedback [+ve (oscillators) feedback]
2. Degenerative feedback [-ve (amplifier) feedback]

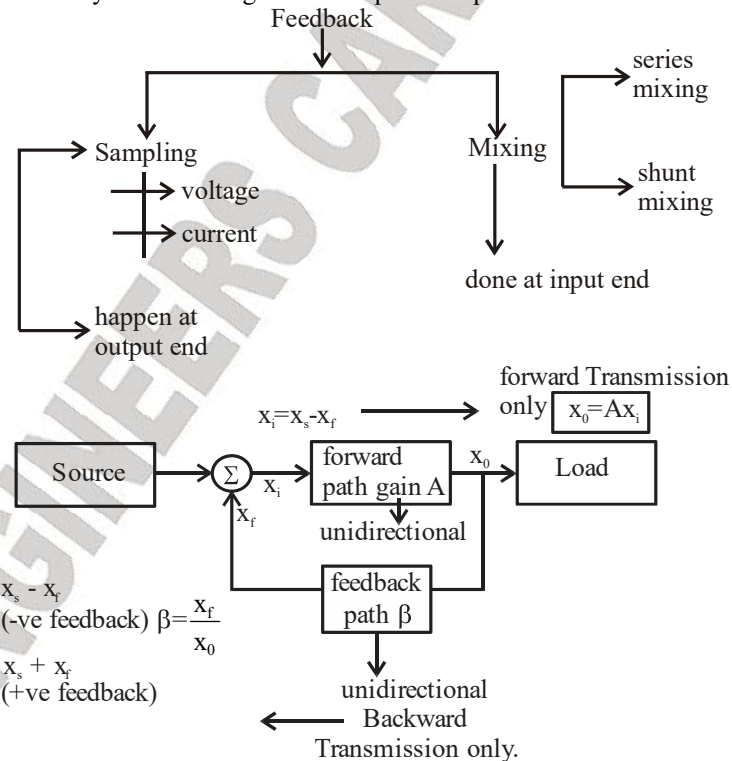
In amplifier design negative feedback is applied to effect one or more of the following property
Feedback in practical case is never 100%.

Feedback decide the fraction of output which is given back to the input.

5.1.1 General structure of the feedback

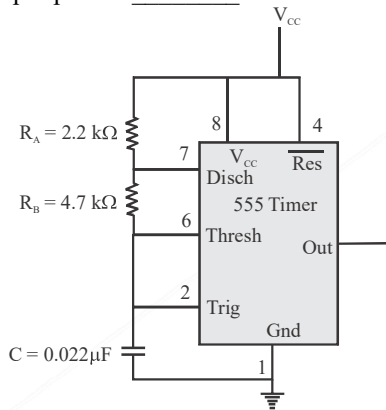
1. Gain = $\frac{\text{output}}{\text{input}} \Rightarrow \text{finite}$ [for all practical stable system]
2. Gain = finite \rightarrow mean output following input
3. Gain $\Rightarrow \infty \Rightarrow \frac{\text{finite}}{\text{zero}} \rightarrow \frac{\text{output}}{\text{input}} \Rightarrow \text{unstable system}$

If gain is finite then output is finite for zero input. If this arrangement is intended arrangement then the system arrangement is stable. If the gain of the system become finite by chance then the system is unstable because the system with ∞ gain are not practical possible.



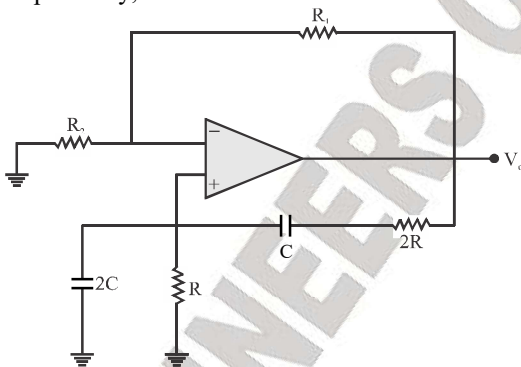
GATE QUESTIONS

1. In the table multivibrator circuit shown in the figure, the frequency of oscillation (in kHz) at the output pin 3 is _____



[GATE - 2016]

2. The circuit shown in the figure has an ideal opamp. The oscillation frequency and the condition to sustain the oscillations, respectively, are



[GATE - 2015]

- (a) $\frac{1}{CR}$ and $R_1 = R_2$
- (b) $\frac{1}{CR}$ and $R_1 = 4R_2$
- (c) $\frac{1}{2CR}$ and $R_1 = R_2$

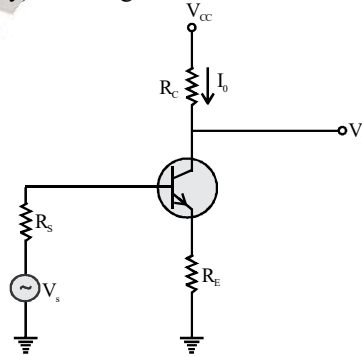
- (d) $\frac{1}{2CR}$ and $R_1 = 4R_2$

3. The desirable characteristics of a transconductance amplifier are

[GATE - 2014]

- (a) High input resistance and high output resistance
- (b) High input resistance and low output resistance
- (c) Low input resistance and high output resistance
- (d) Low input resistance and low output resistance

4. The feedback topology in the amplifier circuit (the base bias circuit is not shown for simplicity) in the figure is



[GATE - 2014]

- (a) Voltage shunt feedback
- (b) Current series feedback
- (c) Current shunt feedback
- (d) Voltage series feedback

5. In the ac equivalent circuit shown in the figure, if i_m is the input current and R_F is very large, the type of feedback is

ESE OBJ QUESTIONS

1. An amplifier, without feedback, has a gain A . The distortion at full output is 10%. The distortion is reduced to 2% with negative feedback (feedback factor $\beta = 0.03$). The values of A and A' (i.e., the gain with feedback) are, respectively, nearly

[EC ESE - 2018]

- (a) 133.3 and 18.5 (b) 133.3 and 26.7
(c) 201.3 and 26.7 (d) 201.3 and 18.5

2. In a sinusoidal oscillator, sustained oscillation will be produced only if the loop gain (at the oscillation frequency) is

[EC ESE - 2016]

- (a) Less than unity but not zero
(b) Zero
(c) Unity
(d) Greater than unity

3. Consider the following statements regarding Wien Bridge oscillator:

1. It has a larger bandwidth than the phase shift oscillator
2. It has a smaller bandwidth than the phase shift oscillator
3. It has 2 capacitors while the phase shift oscillator has 3 capacitors.
4. It has 3 capacitors while the phase shift oscillator has 2 capacitors.

Which of the above statements are correct ?

[EC ESE - 2016]

- (a) 1 and 3 only (b) 2 and 4 only
(c) 1 and 4 only (d) 2 and 3 only

4. If the quality factor of a single-tuned amplifier is doubled, the bandwidth will

[EC ESE - 2016]

- (a) Remain the same
(b) Become half
(c) Become double
(d) Become four times

5. Consider the following statements related to oscillator circuits.

1. The tank circuit of a Hartley oscillator is made up of a tapped capacitor and a common inductor.

2. The tank circuit of a Colpitts oscillator is made up of a tapped capacitor and a common inductor.

3. The Wien bridge oscillator is essentially a two-stage amplifier with an RC bridge in the first stage and the second stage serving as an inverter.

4. Crystal oscillators are fixed frequency oscillators with a high Q-factor.

Which of the above statements are correct?

[EC ESE - 2016]

- (a) 1, 2 and 3 only (b) 2, 3 and 4 only
(c) 1, 2 and 4 only (d) 1, 3 and 4 only

6. A negative feedback of $\beta = 2.5 \times 10^{-3}$ is applied to an amplifier of open-loop gain 1000. What is the change in overall gain of the feedback amplifier, if the gain of the internal amplifier is reduced by 20%?

[EE ESE - 2016]

- (a) 295.7 (b) 286.7
(c) 275.7 (d) 266.7

7. In order to generate a square wave from a sinusoidal input signal, one can use

[EE ESE - 2015]

1. Schmitt trigger circuit
2. Clippers and amplifiers
3. Monostable multivibrator

Which of the above statements are correct?

- (a) 1, 2 and 3
(b) 1 and 2 only
(c) 1 and 3 only
(d) 2 and 3 only

8. In a voltage-series feedback amplifier with open loop gain A_v and the feedback factor β , the input resistance becomes

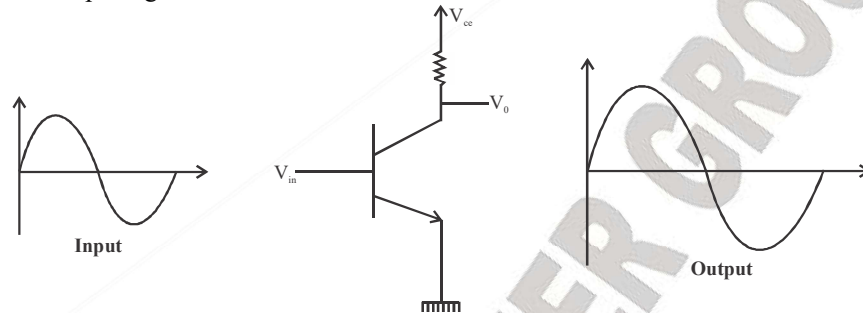
[EE ESE - 2015]

CHAPTER - 6

POWER AMPLIFIERS

6.1 POWER AMPLIFIER/LARGE SIGNAL AMPLIFIER

1. It is the last stage in multistage amplifier.
2. It is defined as ability of amplifier to convert available output dc power into ac power with the application of input signal.



6.2 HARMONIC DISTORTION

1. In a power amplifier, signal amplitudes is very large. Hence signal is operated in linear & non-linear portion of input characteristics. So we get harmonics in output and harmonic distortion is present at output.
2. It is a non-linear distortion.

3. Fourier series expansion of collector current of power transistor is:

$$i_c = I_c + B_0 + B_1 \cos \omega t + B_2 \cos 2\omega t + \dots$$

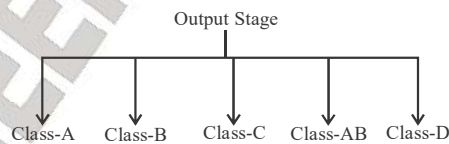
where $I_c + B_0$ is DC

$B_1 \cos \omega t$ is fundamental

$B_2 \cos 2\omega t$ is harmonics

6.3 CLASSIFICATION OF OUTPUT STAGE

Output stages are classified according to the collector current wave form that result when an input is applied



Second harmonic distortion, $D_2 = \left| \frac{B_2}{B_1} \right|$

Third harmonic distortion, $D_3 = \left| \frac{B_3}{B_1} \right|$

AC power output due to fundamental component

$$P_{ac} = I_{rms}^2 R_0 = \left(\frac{B_1^2}{2} \right) R_0 \Rightarrow P_1$$

GATE QUESTIONS

1. Which one of the following statements is correct about an ac-coupled common-emitter amplifier operating in the mid band region?

[GATE - 2016]

- (a) The device parasitic capacitances behave like open circuits, whereas coupling and bypass capacitances behave like short circuits.
- (b) The device parasitic capacitances coupling capacitances and bypass capacitances behave like open circuits.
- (c) The device parasitic capacitances, coupling capacitances and bypass capacitances behave like short circuits.
- (d) The device parasitic capacitances behave like short circuits, whereas coupling and bypass capacitances behave like open circuits.

2. Crossover distortion behavior is characteristic of

[GATE - 1999]

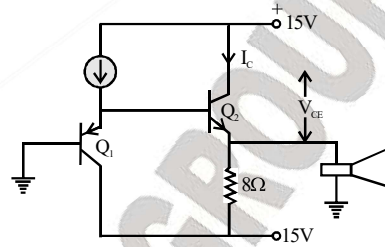
- (a) Class A output stage
- (b) Class B output stage
- (c) Class AB output stage
- (d) Common-base output stage

3. A power Amplifier delivers 50 W output at 50% efficiency. The ambient temperature is 25°C. If the maximum allowable junction temperature is 150°C, then the maximum thermal resistance θ_{jc} that can be tolerated is _____.

[GATE - 1995]

4. The circuit shown in the figure supplies power to an 8Ω speaker, LS. The values of I_C and V_{CE} for this circuit will be $I_C =$ _____ and $V_{CE} =$ _____.

[GATE - 1995]



5. A class-A transformer coupled, transistor power Amplifier is required to deliver a power output of 10 watts. The maximum power Rating of the transistor should not be less than

[GATE - 1994]

- (a) 5W
- (b) 10W
- (c) 20W
- (d) 40W

6. In a transistor push-pull Amplifier

[GATE - 1993]

- (a) There is no d.c. present in the output
- (b) There is no distortion in the output
- (c) There is no even harmonics in the output
- (d) There is no odd harmonics in the output

7. In case of class A amplifiers the ratio (efficiency of transformer coupled amplifier)/(efficiency of a transformer less amplifier) is

[GATE - 1987]

- (a) 2.9
- (b) 1.36
- (c) 1.0
- (d) 0.5

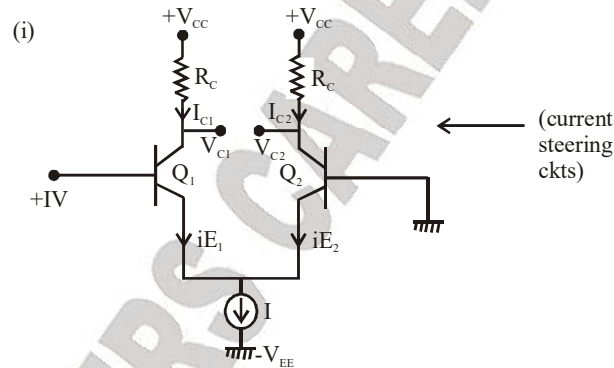
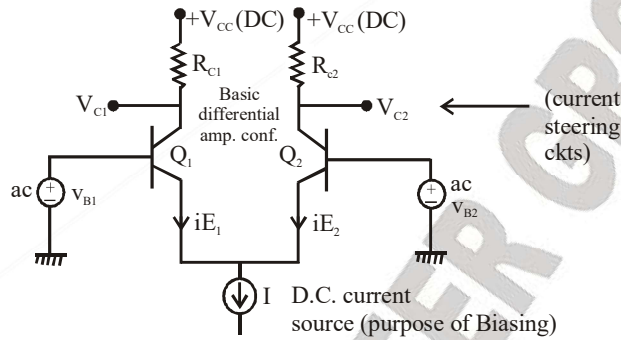
ESE OBJ QUESTIONS

1. The Class-B- pull amplifier is an efficient two-transistor circuit, in which the two transistors operate in the following way:
[EE ESE - 2016]
- (a) Both transistors operate in the active region throughout the negative ac cycle
(b) Both transistors operate in the active region for more than half – cycle but less than a whole cycle
(c) One transistor conducts during the positive half-cycle and the other during the negative half-cycle
(d) Full supply voltage appears across each of the transistors
2. Which of the following is the principal factor that contributes to the doubling of the conversion efficiency in a transformer coupled amplifier?
[EE ESE - 2015]
- (a) Reducing the power dissipated in the transistor
(b) Eliminating the power dissipation in the transformer
(c) Elimination of dc power dissipated in the load
(d) Impedance matching of the transformer
3. A power amplifier operated from 12v battery gives an output of 2W. The maximum collector current in the circuit is
[EC ESE - 2015]
- (a) 166.7 μ A (b) 166.7mA
(c) 166.7 mA (d) 16.67 mA
4. For a transformer, the load connected to the secondary has an impedance of 8Ω . Its reflected impedance on primary is observed to be 648Ω . The turns ratio of this transformer is
[EE ESE - 2014]
- (a) 6 : 1 (b) 10 : 1
(c) 9 : 1 (d) 8 : 1
5. A power amplifier with a gain of $100\angle 0^\circ$ has an output of 12v at 1.5 kHz along with a second harmonic content of 25 percent. A negative feedback is to be provided to reduce the harmonic content of the output to 2.5 percent. What should be the gain of the feedback path and the level of signal input to the overall system, respectively ?
[EE ESE - 2014]
- (a) 0.9 and 0.12 V (b) 0.9 and 12 V
(c) 0.09 and 1.2 V (d) 9 and 0.12V
6. An output signal of a power amplifier has amplitudes of 2.5 V fundamental, 0.25 V, second harmonic and 0.1 V third harmonic. The total percentage harmonic distortion of the signal is
[EC ESE - 2012]
- (a) 12.8% (b) 10.8%
(c) 6.4% (d) 1.4%
7. The second-harmonic component in the output of a transistor amplifier, without feedback, is B_2 . The second harmonic component, with negative feedback B_2' is equal to (where A = Amplifier gain and β = feedback factor).
[EC ESE - 2012]
- (a) $\frac{B_2}{1 + A\beta}$ (b) $B_2(1 + A\beta)$
(c) $\frac{B_2}{\beta}$ (d) $\frac{B_2}{A\beta}$
8. **Statement (I)** : Much of the distortion introduced in large signal amplifiers is eliminated by push –pull circuit
Statement (II) : The signals applied to the two transistors applied to the two transistors in push -pull mode are 180° out of phase
[EE ESE - 2012]

CHAPTER - 7
DIFFERENTIAL AMPLIFIERS

7.1 DIFFERENTIAL AMPLIFIER (BJT PAIR)

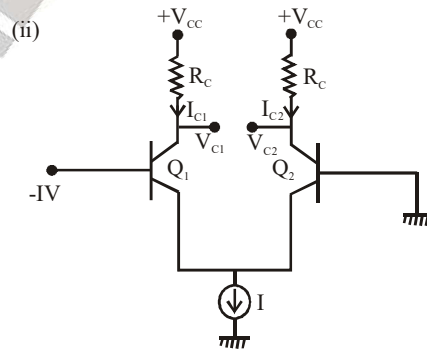
It is also known as emitter coupled differential amplifier. It consists of 2 matched transistors Q_1 and Q_2 , whose emitters are joined together.



$$\frac{V_{cc} - V_{c1}}{R_c} = I_{c1}$$

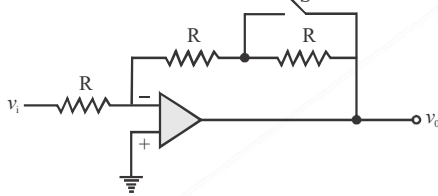
$$V_{cc} - I_{c1}R_c = V_{c1}$$

$$V_{cc} - I_{c2}R_c = V_{c2}$$



ESE OBJ QUESTIONS

1. The magnitude of the gain $\frac{v_o}{v_i}$ in the inverting op-amp circuit shown in the figure is x with switch S open. When switch S is closed, the magnitude of the gain will be



[EE ESE - 2018]

- (a) x
(c) $2x$

- (b) $\frac{x}{2}$
(d) $\frac{2}{x}$

2. An op-amp is used in a notch filter. The notch frequency is 2 kHz, lower cut-off frequency is 1.8 kHz and upper cut-off frequency is 2.2 kHz. Then Q of the notch filter is

[EE ESE - 2018]

- (a) 3.5
(c) 4.5

- (b) 4.0
(d) 5.0

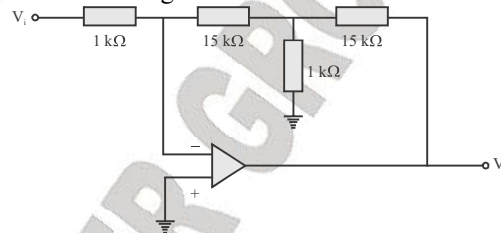
3. In op-amp based inverting amplifier with a gain of 100 and feedback resistance of $47\text{k}\Omega$, the op-amp input offset voltage is 6 mV and input bias current is 500 nA. The output offset voltage due to an input offset voltage and an input bias current, are

[EE ESE - 2018]

- (a) 300 mV and 23.5 mV
(b) 606 mV and 47.0 mV

- (c) 300 mV and 47.0 mV
(d) 606 mV and 23.5 mV

4. What is the gain of the amplifier circuit as shown in the figure?



[EE ESE - 2018]

- (a) 255
(c) -31

- (b) 31
(d) -255

5. **Statement (I) :**

In ideal case, the inverting and non-inverting input terminals of an operational amplifier are almost at the same potential.

- Statement (II) :**

It is common practice to connect the inverting and non-inverting terminals to the same point.

Codes:

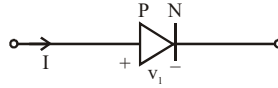
[EE ESE - 2018]

- (a) Both Statement (I) and Statement (II) are individually true and Statement (II) is the correct explanation of Statement (I)
(b) Both Statement (I) and Statement (II) are individually true but Statement (II) is not the correct explanation of Statement (I)
(c) Statement (I) is true but Statement (II) is false
(d) Statement (I) is false but Statement (II) is true

CHAPTER - 8

FET AND MOSFET

8.1 INTRODUCTION



$$\omega_{dep} = \left[\frac{2\epsilon}{q} \left[\frac{1}{N_A} + \frac{1}{N_B} \right] [V_{bi} + V_R]^{1/2} \right]^{1/2}$$

ω_{dep} = Basic depletion with standard formula

V_{bi} = Built in potential or contact potential

$$V_{bi} = V_T \ln \left[\frac{N_A N_D}{n_i} \right]$$

V_R = applied reverse biased

8.1.1 Field Effect Transistor is an unipolar device

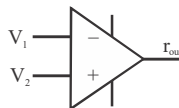
1. JFET-n-type and p-type

2. MOSFET

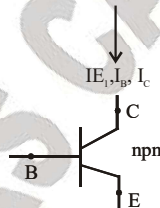
(i) Depletion type MOSFET-n type and p type

(ii) Depletion Enhancement type MOSFET-n type and p type

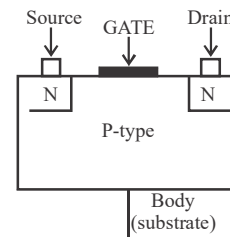
Operational Amplifier



BJT Amplifier



FET Amplifier



3. FET is a unipolar device because the current conduct only due to majority carrier this is known as the field effect transistor.

4. It is field effect transistor that is in which current is controlled by electric field and there is not leakage current and it is less noisy as compared to BJT.

5. Source, Drain and Gate are these Basic terminal of any FET device.

8.1.2 Source

It is the terminal through which majority carriers enter the bar-since carrier come from it ie why is called as source.

8.1.3 Drain

It is the terminal through which majority carrier leaves the channel. They are drain out from this terminal.

GATE QUESTIONS

1. An n-channel enhancement mode MOSFET is biased at $V_{BS} > V_{TH}$ and $V_{DSD} > (V_{BS} - V_{TH})$, where V_{GS} is the gate to source voltage, V_{DS} is the drain to source voltage and V_{TH} is the threshold voltage. Considering channel length modulation effect to be significant, the MOSFET behaves as a

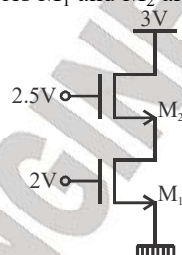
[GATE - 2017]

- (a) Voltage source with zero output impedance
- (b) Voltage source with non-zero output impedance
- (c) Current source with finite output impedance
- (d) Current source with infinite output impedance

2. A MOS capacitor is fabricated on p-type Si (silicon) where the metal work function is 4.1 eV and electron affinity of Si is 4.0 eV, $E_C - E_F = 0.9$ eV; where E_C and E_F are conduction band minimum and the Fermi energy levels of Si, respectively. Oxide $\epsilon_r = 3.9$, $\epsilon_0 = 8.85 \times 10^{-14}$ F/cm, oxide thickness $t_{ox} = 0.1 \mu\text{m}$ and electron charge $q = 1.6 \times 10^{-19}$ C. If the measured flat band voltage of this capacitor is -1 V, then the magnitude of the fixed charge at the oxide semiconductor interface, in nC/cm^2 , is _____.

[GATE - 2017]

3. Assuming that transistors M_1 and M_2 are identical and have a threshold voltage of 1 V, the state of transistors M_1 and M_2 are respectively



[GATE - 2017]

- (a) Saturation, Saturation
- (b) Linear, Linear

- (c) Linear, Saturation
- (d) Saturation, Linear

4. In the circuit shown, transistor Q_1 and Q_2 are biased at a collector current of 2.6 mA. Assuming the transistor current gains are sufficiently large to assume collector current equal to emitter current and thermal voltage of 26 mV, the magnitude of voltage gain V_o/V_s in the mid band frequency range is _____ (up to second decimal place).

[GATE - 2017]

5. Consider the following statements for a metal oxide semiconductor field effect transistor (MOSFET)

P: As channel length reduces, OFF-state current increases

Q: As channel length reduces, output resistance increases

R: As channel length reduces, threshold voltage remains constant

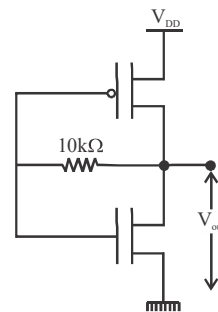
S: As channel reduces, ON current increases

Which of the above statements are INCORRECT?

[GATE - 2017]

- (a) P and Q
- (b) P and S
- (c) Q and R
- (d) R and S

6. What is the voltage V_{out} in the following circuit?



[GATE - 2017]

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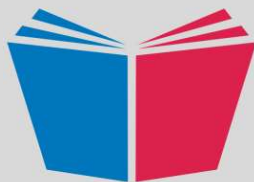
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CHAPTER - 1

NUMBER SYSTEM

1.1 DATA REPRESENTATION

Magnitude Representation	Complement Representation
1. Unsigned magnitude representation (positive): No sign bit 2. Signed magnitude representation (positive, negative): One extra bit (sign) as MSB	1. $(r-1)$'s complement: (positive, negative) 2. R 's complement: (positive, negative) MSB = 0 (positive) MSB = 1 (negative)

1.1.1 Sign Magnitude Representation

“+” sign before a number indicate that it is positive (+ve) number and negative (-ve) sign before a number indicate that it is -ve number.

Replace +ve = 0 (MSB); -ve = 1 (MSB)

Example.

$$(+1100101)_2 \rightarrow (01100101)_2$$

$$(+101.001)_2 \rightarrow (0101.001)_2$$

$$(-10010)_2 \rightarrow (110010)_2$$

$$(-110.101)_2 \rightarrow (1110.101)_2$$

1.1.2 Signed Representation

Range is identical as that of 1's complement is also has 2 unique representation for zero

$$\text{Range} = -(2^{n-1} - 1) \text{ to } +(2^{n-1} - 1)$$

$$(n = 7): (-63) \text{ to } (+63)$$

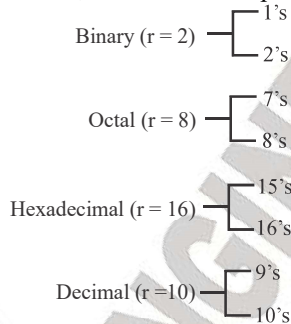
1.1.3 Complement

There are two type of complements:

1. $(r-1)$'s complement

2. (r) 's complement

Where, r is base of complement



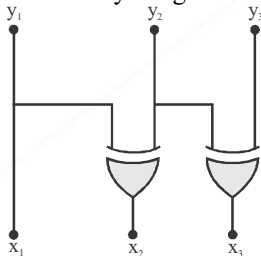
$(r-1)$'s complements: To determine the complement subtract the given no from maximum number possible in base.

ASSIGNMENT

1. When signed numbers are used in binary arithmetic, then which one of the following notations would have unique representation for zero?

- (a) Sign magnitude
 (b) 1's complement
 (c) 2's complement
 (d) 9's complement

2. In the following codes a binary number $Y_1Y_2Y_3$ is converted by the given circuit.



- (a) Excess-3 Code (b) Gray Code
 (c) Decimal Code (d) BCD Code

3. Addition of all the gray code to convert decimal (0-9) into gray code is:

- (a) 129 (b) 108
 (c) 69 (d) 53

4. Input



- (a) + 255 (b) +127
 (b) +31 (d) Zero

5. If $(123)_5 = (X3)_Y$, then the number of possible values of X is

- (a) 4 (b) 3
 (c) 2 (d) 1

6. A computer has the following negative numbers stored in binary form as shown. The wrongly stored number is:

- (a) -37 as 11011011

- (b) -89 as 10100111
 (c) -48 as 11101000
 (d) -32 as 11100000

7. Octal equivalent of hexadecimal AF AF AF is

- (a) 53276757 (b) 76727673
 (c) 53727657 (d) 76727672

8. $(177)_8 + 1 = (X)_8$, the value of x is

- (a) 178 (b) 179
 (c) 200 (d) None of these

9. Noting that $3^2=9$, formulate a simple procedure for converting base-3 numbers directly to base -9 use the procedure to convert $(2110201102220112)_3$ to base 9.

- (a) $(66582614)_9$
 (b) $(2206112414)_9$
 (c) $(73642815)_9$
 (d) None of these

10. Identify the first 10 decimal digits in Base 4 number system

- (a) 0, 1, 2, 3, 4, 5, 6, 0, 1, 2
 (b) 0, 1, 2, 3, 4, 5, 6, 7, 0, 1
 (c) 0, 1, 2, 3, 10, 11, 12, 13, 14
 (d) 0, 1, 2, 3, 10, 11, 12, 13, 20, 21

11. What is the 11's complement of $(935)_{12}$?

- (a) 124_{11} (b) 234_{10}
 (c) 286_{12} (d) 330_{10}

12. X and Y are successive digits in a positional number system. Also $XY = 25_{10}$ and $YX = 31_{10}$. Determine the Radix value of the system and value of X and Y.

- (a) 6, 4, 2 (b) 7, 3, 4
 (c) 7, 4, 3 (d) 6, 4, 3

13. Consider the signed Binary numbers $A = 01000110$ and $B = 11010011$, where B is in 2's complement form. Match the following.

List-I

List-II

GATE QUESTIONS

1. The number of bytes required to represent the decimal number 1856357 in packed BCD (Binary Coded Decimal) from is _____.
[GATE - 2014]
2. Which of the following is an invalid state in an 8-4-2-1 Binary coded decimal counter
[GATE - 2014]
- (a) 1 0 0 0 (b) 1 0 0 1
(c) 0 0 1 1 (d) 1 1 0 0
3. The two numbers represented in signed 2's complement form are $P=11101101$ and $Q=11100110$. If Q is subtracted from P , the value obtained in signed 2's complement form is
[GATE - 2008]
- (a) 100000111 (b) 00000111
(c) 11111001 (d) 111111001
4. $X=01110$ and $Y=11001$ are two 5-bit binary numbers represent in two's complement format. The sum of X and Y represented in two's complement format using 6 bit is :
[GATE - 2007]
- (a) 100111 (b) 001000
(c) 000111 (d) 101001
5. The Octal equivalent of HEX and number AB.CD is
[GATE - 2007]
- (a) 253.314 (b) 253.632
(c) 526.314 (d) 526.632
6. A new Binary Coded Pentary (BCP) number system is proposed in which every digit of a base-5 number is represented by its corresponding 3-bit binary code. For example the base-5 number 24 will be represented by its BCP code 010100. In the numbering system the BCP code 100010011001 corresponds to the following number in base -5 systems
[GATE - 2006]
- (a) 423 (b) 1324
(c) 2201 (d) 4231
7. Decimal 43 in Hexadecimal and BCD number system is respectively
[GATE - 2005]
- (a) B2, 0100 0011 (b) 2B, 0100 0011
(c) 2B, 0011 0100 (d) B2, 0100 0100
8. The range of signed decimal numbers that can be represented by 6-bite 1's complement number is
[GATE - 2004]
- (a) -31 to +31 (b) -63 to +64
(c) -64 to +63 (d) -32 to +31
9. 11001, 1001 and 111001 correspond to the 2's complement representation of which one of the following sets of number?
[GATE - 2004]
- (a) 25, 9 and 57 respectively
(b) -6, -6 and -6 respectively
(c) -7, -7 and -7 respectively
(d) -25, -9 and -57 respectively
10. -bit 2's complement representation of a decimal number is 1000. The number is
[GATE - 2002]
- (a) +8 (b) 0
(c) -7 (d) -8
11. The 2's complement representation of -17 is
[GATE - 2001]
- (a) 01110 (b) 01111
(c) 11110 (d) 10001

CHAPTER - 2

LOGIC GATES & BOOLEAN ALGEBRA

2.1 LOGIC GATE

1. The fundamental building block of digital system. Logic gate means that output and input pattern of gate are assigned logically.

2. The inter connection of Gate to perform a variety of logical operation is called logic design.

3. The input and output of logic gate can occur only in two levels. These level are termed as high (1) and Low (0) simply.

4. Truth table show how the logic circuit o/p respond to various combination of logic level of i/p.

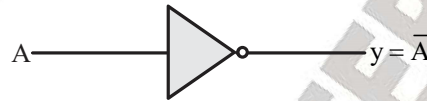
There are various types of gates:

(i) Basic Gates: NOT, AND & OR

(ii) Universal Gate: NAND & NOR

(iii) EXOR & ENOR: Arithmetic, comparator, code converter, parity generator and parity checker.

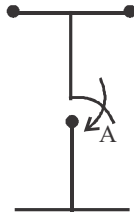
1. NOT Gate



Truth Table

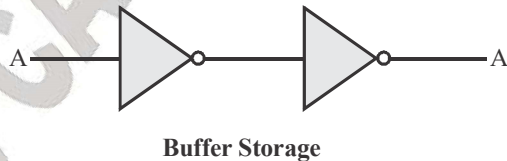
A	y
0	1
1	0

(i)



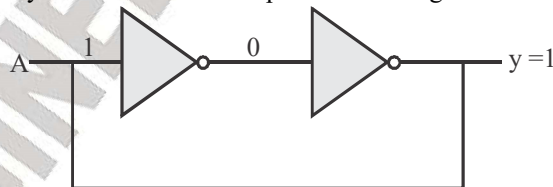
Switching Diagram

(ii)



Buffer Storage

(iii) It act as basic memory element or cross coupled latch storage element

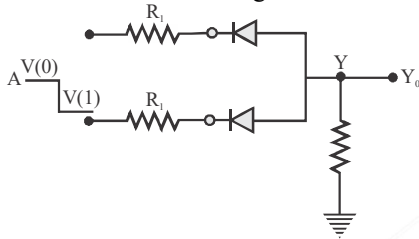


Basic Memory Element

Or mostly represented as

ASSIGNMENT

1. The circuit shown in the figure is:



- (a) Positive logic 'OR' circuit
- (b) Negative logic 'OR' circuit
- (c) Positive logic 'AND' circuit
- (d) Negative logic 'AND' circuit

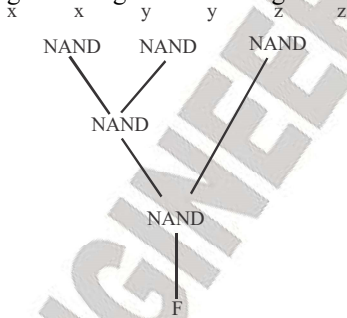
2. Which of the following logic expression is incorrect?

- (a) $1 \oplus 0 = 1$
- (b) $1 \oplus 1 \oplus 0 = 1$
- (c) $1 \oplus 1 \oplus 1 = 1$
- (d) $1 \oplus 1 = 0$

3. Which of the following Boolean algebra statements represent distributive law:

- (a) $(A+B) + C = A + (B+C)$
- (b) $A \cdot (B+C) = (A \cdot B) + (A \cdot C)$
- (c) $A \cdot (B \cdot C) = (A \cdot B) \cdot C$
- (d) None of these

4. Which expression is computed by the following NAND-gate circuit diagram.



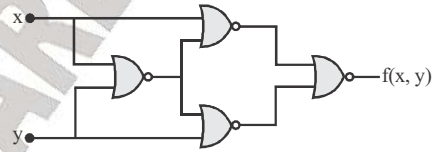
- (a) $X'Y'+Z$
- (b) $(X+Y) Z'$
- (c) $X'Y'Z$
- (d) $X'+Y'+Z'$

5. What is the equivalent Boolean expression in product of sum form for the K-map given below?

	AB			
CD	00	01	11	10
00		1	1	
01	1			1
11	1			1
10		1	1	

- (a) $BD'+B'D$
- (b) $(B+C+D) (B'+C+D')$
- (c) $(B+D') (B'+D)$
- (d) $(B'+D') (B+D)$

6. Identify the logic function performed by the circuit.

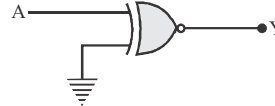


- (a) Exclusive OR
- (b) Exclusive NOR
- (c) NAND
- (d) NOR

7. The binary number 110011 is to be converted to gray code. The number of gates and type required are:

- (a) 6, AND
- (b) 6, XNOR
- (c) 6, XOR
- (d) 5, XOR

8. The output of the logic gate in the figure is



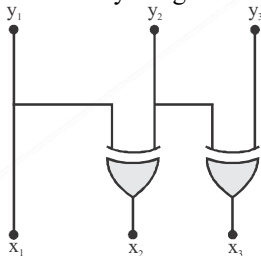
- (a) $AB + AC + BC$
- (b) $A + BC$
- (c) \bar{A}
- (d) $A + B + C$

ASSIGNMENT

1. When signed numbers are used in binary arithmetic, then which one of the following notations would have unique representation for zero?

- (a) Sign magnitude
 (b) 1's complement
 (c) 2's complement
 (d) 9's complement

2. In the following codes a binary number $Y_1Y_2Y_3$ is converted by the given circuit.



- (a) Excess-3 Code
 (b) Gray Code
 (c) Decimal Code
 (d) BCD Code

3. Addition of all the gray code to convert decimal (0-9) into gray code is:

- (a) 129
 (b) 108
 (c) 69
 (d) 53

4. Input



- (a) + 255
 (b) +127
 (c) +31
 (d) Zero

5. If $(123)_5 = (X3)_Y$, then the number of possible values of X is

- (a) 4
 (b) 3
 (c) 2
 (d) 1

6. A computer has the following negative numbers stored in binary form as shown. The wrongly stored number is:

- (a) -37 as 11011011

- (b) -89 as 10100111
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7. Octal equivalent of hexadecimal AF AF AF is

- (a) 53276757
 (b) 76727673
 (c) 53727657
 (d) 76727672

8. $(177)_8 + 1 = (X)_8$, the value of x is

- (a) 178
 (b) 179
 (c) 200
 (d) None of these

9. Noting that $3^2=9$, formulate a simple procedure for converting base-3 numbers directly to base -9 use the procedure to convert $(2110201102220112)_3$ to base 9.

- (a) $(66582614)_9$
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 (c) $(73642815)_9$
 (d) None of these

10. Identify the first 10 decimal digits in Base 4 number system

- (a) 0, 1, 2, 3, 4, 5, 6, 0, 1, 2
 (b) 0, 1, 2, 3, 4, 5, 6, 7, 0, 1
 (c) 0, 1, 2, 3, 10, 11, 12, 13, 14
 (d) 0, 1, 2, 3, 10, 11, 12, 13, 20, 21

11. What is the 11's complement of $(935)_{12}$?

- (a) 124_{11}
 (b) 234_{10}
 (c) 286_{12}
 (d) 330_{10}

12. X and Y are successive digits in a positional number system. Also $XY = 25_{10}$ and $YX = 31_{10}$. Determine the Radix value of the system and value of X and Y.

- (a) 6, 4, 2
 (b) 7, 3, 4
 (c) 7, 4, 3
 (d) 6, 4, 3

13. Consider the signed Binary numbers $A = 01000110$ and $B = 11010011$, where B is in 2's complement form. Match the following.

List-I

List-II

ESE OBJ QUESTIONS

1. The addition of the two numbers $(1A8)_{16} + (67B)_{16}$ will be:
[EC ESE - 2017]
 (a) $(889)_{16}$ (b) $(832)_{16}$
 (c) $(823)_{16}$ (d) $(723)_{16}$
2. The output of a NOR gate is:
[EC ESE - 2017]
 (a) High if all of its inputs are high
 (b) Low if all of its inputs are low
 (c) High if all of its inputs are low
 (d) High if only one of its inputs is low
3. What is the octal equivalent of $(5621.125)_{10}$?
[EE ESE - 2017]
 (a) 1774.010 (b) 12765.100
 (c) 16572.100 (d) 17652.010
4. What is the hexadecimal representation of $(657)_8$?
[EE ESE - 2017]
 (a) 1 AF (b) D 78
 (c) D 71 (d) 32 F
5. Given $(135)_{\text{base } x} + (144)_{\text{base } x} = (323)_{\text{base } x}$. What is the value of base x?
[EC ESE - 2014]
 (a) 5 (b) 3
 (c) 12 (d) 6
6. The number of one's present in the binary representation of $15 \times 256 + 5 \times 16 + 3$ are
[EC ESE - 2014]
 (a) 8 (b) 9
 (c) 9 (d) 11
7. A seven-bit Hamming code is received as 1111101. What is the correct code?
[EC ESE - 2013]
 (a) 1101111 (b) 1011111
 (c) 1111111 (d) 1111011
8. Hexadecimal conversion of decimal number 227 will be:
[EC ESE - 2013]
 (a) A3 (b) E3
 (c) CC (d) C3
9. The decimal equivalent of binary number 10110.11 is:
[EC ESE - 2013]
 (a) 16.75 (b) 20.75
 (c) 16.50 (d) 22.75
10. The BCD code for a decimal number $(874)_{10}$ is:
[EC ESE - 2013]
 (a) $(100001110100)_{\text{BCD}}$
 (b) $(010001111000)_{\text{BCD}}$
 (c) $(100001000111)_{\text{BCD}}$
 (d) $(011110000100)_{\text{BCD}}$
11. Binary data is being represented in size of byte and in 2's complement form. The number of 0's present in representation of $(-127)_{\text{decimal}}$ is
[EC ESE - 2012]
 (a) 8 (b) 7
 (c) 6 (d) 5
12. If $(11X1Y)_8 = (12C9)_{16}$ then the values X and Y are
[EC ESE - 2012]
 (a) 5 and 1 (b) 5 and 7
 (c) 7 and 5 (d) 1 and 5
13. **Statement (I):** 2's complement arithmetic is preferred in digital computers.
Statement (II): The hardware required to obtain the 2's complement of a number, is simple.
[EE ESE - 2012]
 (a) Both statement (I) and statement (II) are individual true and statement (II) is the correct explanation of statement (I).

CHAPTER - 2**LOGIC GATES & BOOLEAN ALGEBRA****2.1 LOGIC GATE**

1. The fundamental building block of digital system. Logic gate means that output and input pattern of gate are assigned logically.

2. The inter connection of Gate to perform a variety of logical operation is called logic design.

3. The input and output of logic gate can occur only in two levels. These level are termed as high (1) and Low (0) simply.

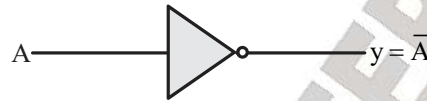
4. Truth table show how the logic circuit o/p respond to various combination of logic level of i/p.

There are various types of gates:

(i) Basic Gates: NOT, AND & OR

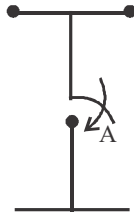
(ii) Universal Gate: NAND & NOR

(iii) EXOR & ENOR: Arithmetic, comparator, code converter, parity generator and parity checker.

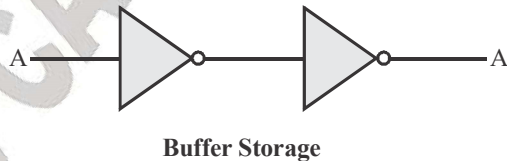
1. NOT Gate**Truth Table**

A	y
0	1
1	0

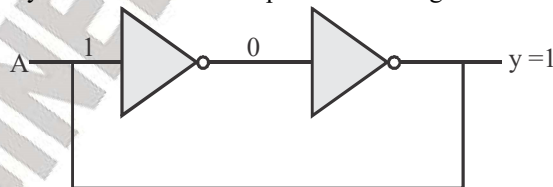
(i)

**Switching Diagram**

(ii)

**Buffer Storage**

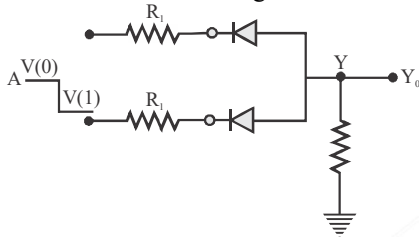
(iii) It act as basic memory element or cross coupled latch storage element

**Basic Memory Element**

Or mostly represented as

ASSIGNMENT

1. The circuit shown in the figure is:



- (a) Positive logic 'OR' circuit
- (b) Negative logic 'OR' circuit
- (c) Positive logic 'AND' circuit
- (d) Negative logic 'AND' circuit

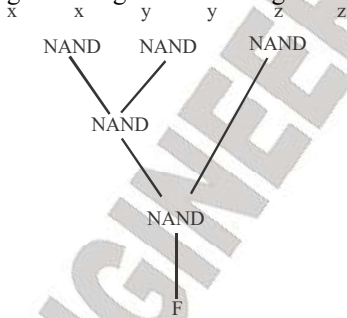
2. Which of the following logic expression is incorrect?

- (a) $1 \oplus 0 = 1$
- (b) $1 \oplus 1 \oplus 0 = 1$
- (c) $1 \oplus 1 \oplus 1 = 1$
- (d) $1 \oplus 1 = 0$

3. Which of the following Boolean algebra statements represent distributive law:

- (a) $(A+B) + C = A + (B+C)$
- (b) $A \cdot (B+C) = (A \cdot B) + (A \cdot C)$
- (c) $A \cdot (B \cdot C) = (A \cdot B) \cdot C$
- (d) None of these

4. Which expression is computed by the following NAND-gate circuit diagram.



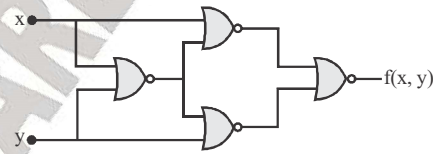
- (a) $X'Y'+Z$
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- (c) $X'Y'Z$
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5. What is the equivalent Boolean expression in product of sum form for the K-map given below?

	AB			
CD	00	01	11	10
00		1	1	
01	1			1
11	1			1
10		1	1	

- (a) $BD'+B'D$
- (b) $(B+C+D) (B'+C+D')$
- (c) $(B+D') (B'+D)$
- (d) $(B'+D') (B+D)$

6. Identify the logic function performed by the circuit.

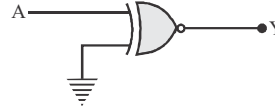


- (a) Exclusive OR
- (b) Exclusive NOR
- (c) NAND
- (d) NOR

7. The binary number 110011 is to be converted to gray code. The number of gates and type required are:

- (a) 6, AND
- (b) 6, XNOR
- (c) 6, XOR
- (d) 5, XOR

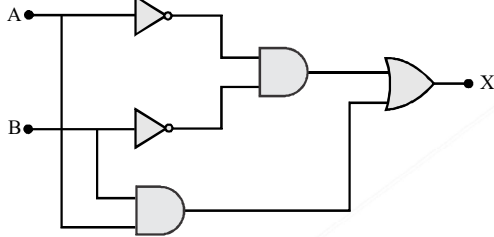
8. The output of the logic gate in the figure is



- (a) $AB + AC + BC$
- (b) $A + BC$
- (c) \bar{A}
- (d) $A + B + C$

GATE QUESTIONS

1. A and B are the logical inputs and X is the logical output shown in the figure. The output X is related to A and B by



[GATE - 2017]

- (a) $X = \bar{A}B + \bar{B}A$
- (b) $X = AB + \bar{B}A$
- (c) $X = AB + \bar{A}\bar{B}$
- (d) $X = \bar{A}\bar{B} + \bar{B}A$

2. Figure 1 shows a 4-bit ripple carry adder realized using full adders and figure 2 shows the circuit of a full adder (FA). The propagation delay of the XOR, AND and OR gates in figure 2 are 20ns, 15ns and 10 ns, respectively. Assume all the inputs to the 4-bit adder are initially reset to 0.

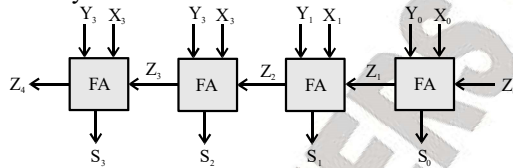


Figure-1

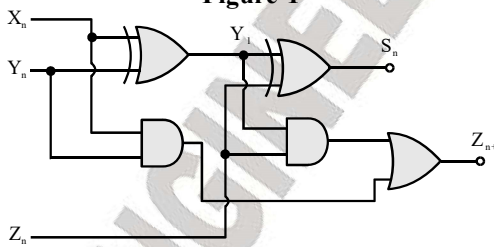
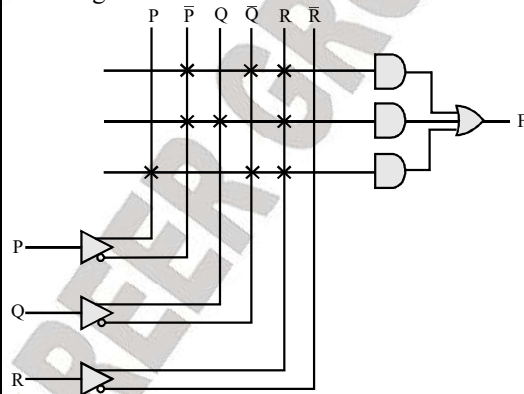


Figure-2

At $t = 0$, the inputs to the 4-bit adder are changed to $X_3X_2X_1X_0 = 1100$, $Y_3Y_2Y_1Y_0 =$

0100 and $Z_0 = 1$. The output of the ripple carry adder will be stable at t (in ns) = [GATE - 2017]

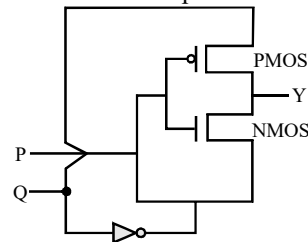
3. A programmable logic array (PLA) is shown in the figure.



The Boolean function F implemented is [GATE - 2017]

- (a) $\bar{P}QR + \bar{P}Q\bar{R} + P\bar{Q}\bar{R}$
- (b) $(\bar{P} + \bar{Q} + R)(\bar{P} + Q + R) + (P + \bar{Q} + \bar{R})$
- (c) $\bar{P}\bar{Q}R + \bar{P}QR + P\bar{Q}\bar{R}$
- (d) $(\bar{P} + \bar{Q} + R)(\bar{P} + Q + R) + (P + \bar{Q} + \bar{R})$

4. For the circuit shown in figure, P and Q are the inputs and Y is the output.



The logic implemented by the circuit is [GATE - 2017]

ESE OBJ QUESTIONS

1. A product of sums (POS) expression leads to what kind of logic circuit?
[EC ESE - 2018]
- (a) OR – AND circuit
(b) NOR-NOR circuit
(c) AND-OR-INVERT circuit
(d) NAND – NAND circuit
2. If only one multiplexer and one inverter are allowed to be used to implement any Boolean function of n variables, what is the maximum size of the multiplexer needed?
[EC ESE - 2017]
- (a) 2^{n-2} line to 1 line
(b) 2^{n-1} line to 1 line
(c) 2^{n+1} line to 1 line
(d) 2^{n+2} line to 1 line
3. The simplification in minimal sum of product (SOP) of
 $Y = F(A, B, C, D)$
 $= \sum_m(0, 2, 3, 6, 7) + \sum(8, 10, 11, 15)$
Using K-maps is
[EC ESE - 2017]
- (a) $Y = AC + B\bar{D}$ (b) $Y = A\bar{C} + B\bar{D}$
(c) $Y = \bar{A}\bar{C} + \bar{B}\bar{D}$ (d) $Y = \bar{A}\bar{C} + \bar{B}\bar{D}$
4. A circuit outputs a digit in the form of 4 bits. 0 is represented by 0000, 1 is represented by 0001,, 9 by 1001. A combinational circuit is to be designed which takes 4 bits as input and output as 1, if the digit is ≥ 5 , and 0 otherwise. If only AND, OR and NOT gates may be used, What is the minimum number of gates required?
[EC ESE - 2017]
- (a) 4 (b) 3
(c) 2 (d) 1
5. How many 3 to 8 line decoders with an enabler input are needed to construct a 6 to 64 line decoder without using any other logic gates?
[EC ESE - 2017]
- (a) 11 (b) 10
(c) 9 (d) 8
6. The minterm expansion of $F(A, B, C) = AB = \bar{B}\bar{C} + A\bar{C}$ is
[EC ESE - 2017]
- (a) $m_2 + m_4 + m_6 + m_1$
(b) $m_0 + m_1 + m_3 + m_5$
(c) $m_7 + m_6 + m_2 + m_4$
(d) $m_2 + m_3 + m_4 + m_5$
7. The logical expression, $AB\bar{C} + \bar{A}BC + \bar{A}\bar{B}C$.
[EE ESE - 2017]
- (a) $\bar{A}(B+C)$ (b) $\bar{A} + \bar{B} + \bar{C}$
(c) $\bar{A}\bar{B}\bar{C}$ (d) $A(\bar{C} + \bar{B})$
8. The logic function $A + BC$ is the simplified from of which of the following?
[EE ESE - 2015]
- (a) $\overline{AB + BC}$ (b) $\bar{A}\bar{B} + \bar{A}\bar{C}$
(c) \overline{ABC} (d) $(A + B)(A + C)$
9. For a four variable K-Map, if each cell is assigned one integer value in range 0-15 then which is the cells adjacent to the cell corresponding to decimal value 7?
[EE ESE - 2015]
- (a) 3, 5, 6 and 8 (b) 3, 5, 10 and 11
(c) 3, 5, 6 and 15 (d) 4, 6, 8 and 5
10. A binary-to-BCD encoder has four inputs D_0, C_0, B_0 and A_0 and five outputs D, C, B, A and VALID. The outputs D, C, B, A give the proper BCD value of the input and the VALID output is 1 if the input combination is a valid decimal code. If the input combination is an invalid decimal code, the VALID output becomes 0 and all of the D, C, B and A outputs show 0 values. If only NOT gates and 2-input

CHAPTER - 3

COMBINATIONAL IC'S

3.1 INTRODUCTION

1. Gates are available as SSI's.
2. Adder, Multiplexer, Comparators and Encoder's are available in MSI.
3. SSI gates are mainly used for realizing simple Logic functions normally encountered in inter-counting.

3.1.1 Sequential logic

Logic circuits whose output are determined by the sequence in which input signals are applied

3.1.2 Glitch

A momentary (short pulse) Duration pulse.

For any logic Design it is always essential to design a product which meets the requirement as:

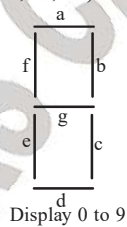
1. Minimum cost
2. Minimum space requirement
3. Maximum speed of operation
4. Easy availability of component
5. Ease of inter connection of component
6. Easy to Design

Example.

Basic Tool used in combinational circuit analysis is Karnaugh map (k-Map)

If we design this display by 4 bit then form (0 to 9) = BCD code valid and A to F (all status are invalid)

$$f(A, B, C, D) = \sum(0, 1, 2, 3 \dots 9) + d \sum(10, 11, 12, 13, 14)$$

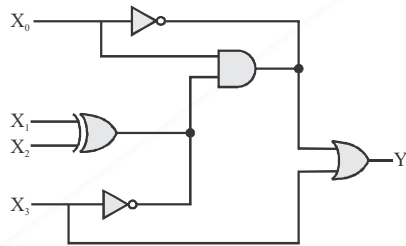


CD	00	01	11	10
AB	1	1	1	1
01	1	0	1	0
11	x	x	x	x
10	1	1	x	x

$$f(A, B, C, D) = \bar{B} + \bar{C}\bar{D} + CD$$

GATE QUESTIONS

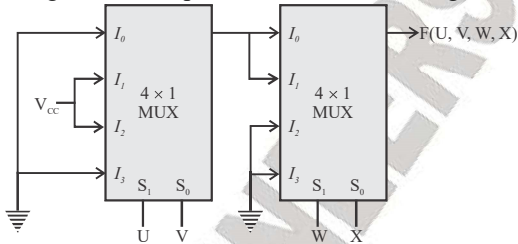
1. The logic gates shown in the digital circuit below use strong pull-down nMOS transistors for LOW logic level at the outputs. When the pull-downs are off, high-value resistors set the output logic levels to HIGH (i.e. the pull-ups are weak). Note that some nodes are intentionally shorted to implement “wired logic”. Such shorted nodes will be HIGH only if the outputs of all the gates whose outputs are shorted are HIGH.



The number of distinct values $X_3 X_2 X_1 X_0$ (out of the 16 possible values) that give $Y = 1$ is _____.

[GATE - 2018]

2. A four-variable Boolean function is realized using 4×1 multiplexes as shown in the figure.

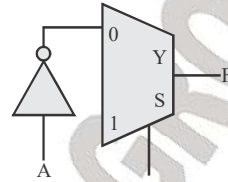


The minimized expression for $F(\text{Uttar Pradesh } V, W, X)$ is

[GATE - 2018]

- (a) $(UV + \bar{U}\bar{V}) \bar{W}$
- (b) $(UV + \bar{U}\bar{V})(\bar{W}\bar{X} + \bar{W}X)$
- (c) $(U\bar{V} + \bar{U}V) \bar{W}$
- (d) $(U\bar{V} + \bar{U}V)(\bar{W}\bar{X} + \bar{W}X)$

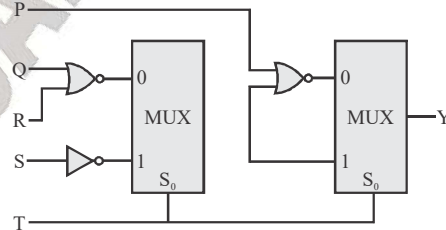
3. Consider the following circuit which uses a 2-to-1 multiplexer as shown in the figure below. The Boolean expression for output F in terms of A and B is



[GATE - 2016]

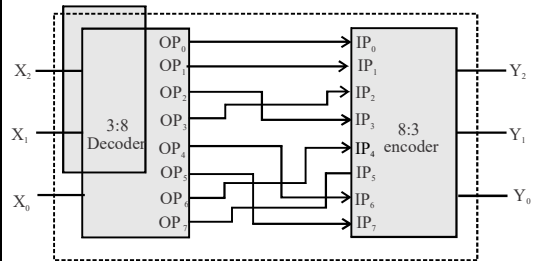
- (a) $A \oplus B$
- (b) $\bar{A} + B$
- (c) $A + B$
- (d) $A \oplus \bar{B}$

4. For the circuit shown in figure, the delays of NOR gates, multiplexer and inverters are 2ns, 1.5ns and 1ns, respectively. If all the inputs P, Q, R, S and T are applied at the same time instant, the maximum propagation delay (in ns) of the circuit is _____.



[GATE - 2016]

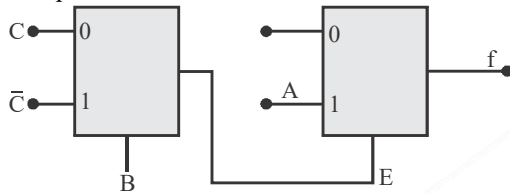
5. Identify the circuit below



[GATE - 2016]

ESE OBJ QUESTIONS

1. The Boolean function 'f' implemented as shown in the figure using two inputs multiplexers is



[EC ESE - 2014]

- (a) $\bar{A}\bar{B}C + A\bar{B}\bar{C}$ (b) $ABC + \bar{A}\bar{B}\bar{C}$
 (c) $\bar{A}BC + \bar{A}\bar{B}\bar{C}$ (d) $\bar{A}\bar{B}C + \bar{A}\bar{B}\bar{C}$

2. A binary full-subtractor

[EC ESE - 2013]

- (a) Consists of two cascaded half-subtractors
 (b) Contains two half-subtractors and one OR gate
 (c) Can subtract any binary number
 (d) Can be made out of a full-adder

3. A digital multiplexer can be used for:

1. Parallel to serial conversion
2. Many-to-one switch
3. Generating memory chip select
4. Code conversion

[EC ESE - 2013]

- (a) 1, 2 and 3 (b) 2 and 3 only
 (c) 1 and 2 only (d) 1 and 3 only

Direction: The following items consists of two statements, one labeled as 'Statement (I)' and the other as 'Statement (II)'. You are to examine these two statements carefully and select the answers to these items using the code given below:

- (a) Both Statement (I) and Statement (II) are individually true and Statement (II) is the correct explanation of Statement (I).
 (b) Both Statement (I) and Statement (II) are individually true but Statement (II) is not the correct explanation of Statement (I).

(c) Statement (I) is true but Statement (II) is false.

(d) Statement (I) is false but Statement (II) is true.

4. Statement (I): The carry look-ahead adder is fast adder.

Statement (II): The carry look-ahead adder generates the carry and the sum digits directly.

[EC ESE - 2012]

- (a) Both Statement (I) and Statement (II) are individually true and Statement (II) is the correct explanation of Statement (I).
 (b) Both Statement (I) and Statement (II) are individually true but Statement (II) is not the correct explanation of Statement (I).
 (c) Statement (I) is true but Statement (II) is false.
 (d) Statement (I) is false but Statement (II) is true.

5. The logic function;

$Out = ab + bc + ca$ defines

1. The output of 3-input XOR gate
2. The output of 1 3-input majority gate
3. The sum output of a full adder
4. The carry output of a full adder

Which of these statements are correct?

[EC ESE - 2011]

- (a) 1 and 3 (b) 2 and 3
 (c) 3 and 4 (d) 2 and 4

6. Assertion (A): A de-multiplexer cannot be used as a decoder.

Reason (R): A de-multiplexer selects one of many outputs, whereas a decoder selects an output corresponding to the coded input.

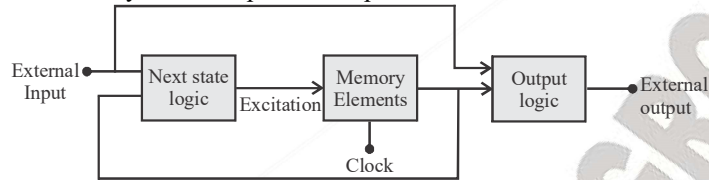
[EC ESE - 2011]

- (a) Both A and R are true and R is the correct explanation of A
 (b) Both A and R are true but R is not a correct explanation of A
 (c) A is true but R is false

CHAPTER - 4
SEQUENTIAL LOGIC ANALYSIS

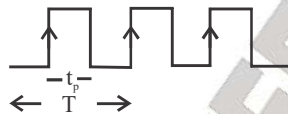
4.1 INTRODUCTION

In combinational circuit the present o/p depend only upon the present input any prior level. (Input condition) does not have any effect on present output.



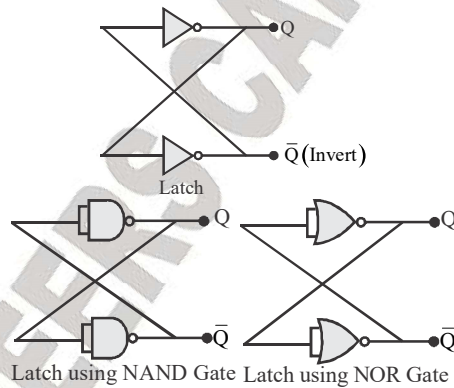
Next state depends upon next state logic and clock is used to receive & store data.

Timing Diagram



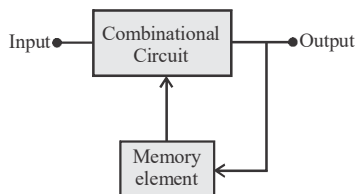
Where $t_p \ll T$

4.1.1 Bit Memory Cell



Bistable (MV) Latch Element (1 Bit memory device)

Block Diagram



ASSIGNMENT

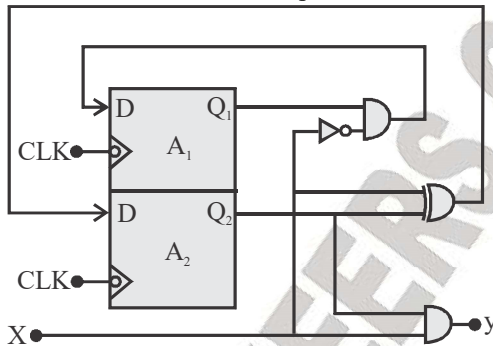
1. A 4-bit register converts the binary stored in the register to its 2's complement value when input $x = 1$. This FFS used are T-FFS. Determine the inputs of flip-flops i.e. T_A, T_B, T_C, T_D .

- (a) $0, 1, (A + B)x, \bar{A}x$
- (b) $(B + C + D)x, (C + D)x, Q_D, x_0$
- (c) $1, 0x, (C + D)x, \overline{(C + D)}x$
- (d) $(B + C)\bar{x}, (C + D)x, D\bar{x}, 0$

2. A counter, constructed using T-FFS, counts the decimal digits according to 2, 4, 2, 1 code. The input T_B is

- (a) $A' B + CD$
- (b) $A' B + BCD$
- (c) $A' B + D$
- (d) $A' B + A' D$

3. A sequential circuit is as shown below. If present states of A_1, A_2 , are 1, 0 and $x = 1$, what is its next state and output

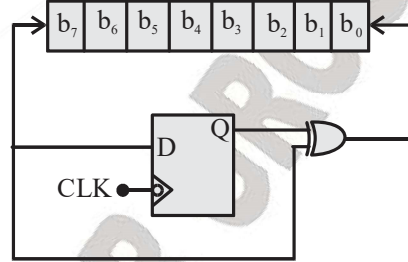


- (a) 0, 1, 0
- (b) 1, 0, 0
- (c) 0, 1, 1
- (d) 1, 1, 1

4. In a 4 bit modulo-6 ripple counter the proportional delay of J-K Flip flop is 50ns. What is the max clock frequency that can used without skipping a count.

- (a) 2MHz
- (b) 4 MHz
- (c) 5 KHz
- (d) 5 MHz

5. In the following logic circuit, the 8 bit left shift register and D-Flip flop is synchronized with same clock. The D-Flip flop is initially cleared. The circuit acts as



- (a) Binary to 2's comp converter
- (b) Binary to EX-3 code converter
- (c) Binary to 1's comp converter
- (d) Binary to Gray code converter

6. A N-bit register is constructed using D-flip-flops. Match the following List- I with List- II

List-I	List-II
A.Parallel in parallel out	(i)(2N-1) clock pulses
B.Serial in serial out	(ii)One clock pulses
C.Parallel in serial out	(iii)N clock pulses
D.Serial in parallel out	(iv)(N-1) clock pulses

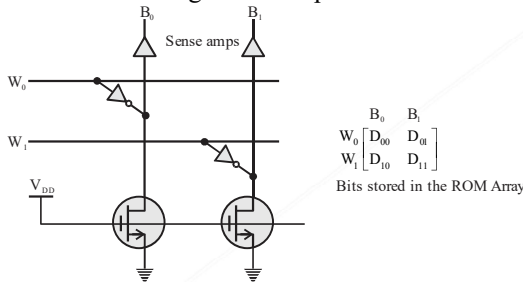
Codes:

- (a) A-iii, B-iv, C-ii, D-i
- (b) A-iv, B-ii, C-i, D-iii
- (c) A-iii, B-ii, C-iv, D-i
- (d) A-ii, B-i, C-iv, D-iii

7. Determine the output of the negative Edge triggered J-K flip flop for the following input waveforms at T_1, T_2, T_3, T_4 . Assume the hold time FF is 0.

GATE QUESTIONS

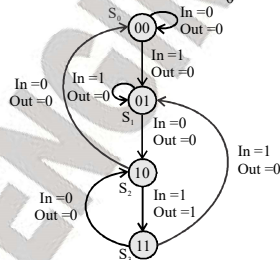
1. A 2×2 ROM array is built with the help of diodes as shown in the circuit below. Here W_0 and W_1 are signals that select the word lines and B_0 and B_1 are signals that are output of the sense amps based on the stored data corresponding to the bit lines during the read operation.



During the read operation, the selected word line goes high and the other word line is in a high impedance state. As per the implementation shown in the circuit diagram above, what are the bits corresponding to D_{ij} (where $i = 0$ or 1 and $j = 0$ or 1) stored in the ROM?

- [GATE - 2018]**
- (a) $\begin{bmatrix} 1 & 0 \\ 0 & 1 \end{bmatrix}$ (b) $\begin{bmatrix} 0 & 1 \\ 1 & 0 \end{bmatrix}$
- (c) $\begin{bmatrix} 1 & 0 \\ 1 & 0 \end{bmatrix}$ (d) $\begin{bmatrix} 1 & 1 \\ 0 & 0 \end{bmatrix}$

2. The state diagram of a finite state machine (FSM) designed to detect an overlapping sequence of three bits is shown in the figure. The FSM has an input 'In' and an output 'out'. The initial state of the FSM is S_0 .

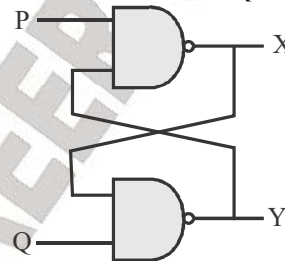


If the input sequence is 10101101001101, starting with the left most bit, then the number of times 'Out' will be 1 is ____

[GATE - 2017]

3. In the latch circuit shown, the NAND gates have non-zero, but unequal propagation delays. The present input condition is: $P = Q = '0'$, if the input condition is changed simultaneously to $P = Q = '1'$, the outputs X and Y are

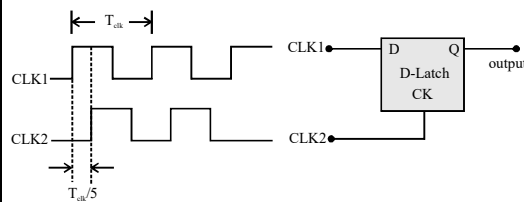
[GATE - 2017]



- (a) $X = '1', Y = '1'$
 (b) Either $X = '1', Y = '0'$ or $X = '0', Y = '1'$
 (c) Either $X = '1', Y = '1'$ or $X = '0', Y = '0'$
 (d) $X = '0', Y = '0'$

4. Consider the D-latch shown in the figure, which is transparent when its clock input CK is high and has zero propagation delay. In the figure, the clock signal CLK1 has a 50% duty cycle and CLK2 is a one-fifth period delayed version of CLK1. The duty cycle at the output of the latch in percentage is ____.

[GATE - 2017]

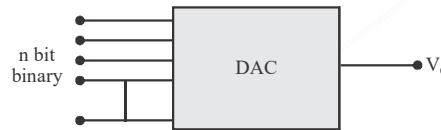


CHAPTER - 5

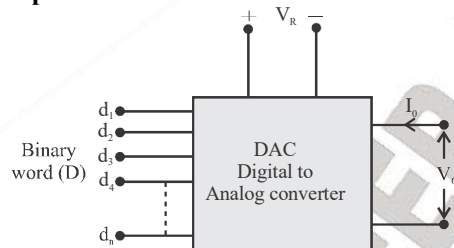
DIGITAL TO ANALOG CONVERTOR

5.1 DIGITAL TO ANALOG CONVERSION

1. It requires insulation of digital information to an equation analog information.
2. Usually refers as coding device.



Digital to analog convertor specification



5.1.1 Types of DAC

1. Weighted resistor DAC
2. R-2R Ladder DAC

5.1.2 Parameter

1. Resolution
2. Analog output voltage
3. V_{FS}
4. % resolution
5. Error / accuracy

5.1.3 General Equation

$$V_o = k \{ V_{FS} (d_1 2^{-1} + d_2 2^{-2} + \dots + d_n 2^{-n}) \}$$

Where, V_{FS} is full scale output voltage k is scaling factor usually "1".

d_1 is MSB with weight of $V_{FS} / 2$

d_n is LSB with weight of $V_{FS} / 2^n$

1. Resolution (D to A converter)

(i) Resolution of DAC is change in analog voltage corresponding to 1 bit LSB increment.

$$\text{Step size} = \text{Resolution} = \frac{V_r}{2^n - 1}$$

Where n is number of bit

v_r is reference voltage corresponding to logic 1.

(ii) It is smallest change in analog output.

CHAPTER - 6***DIGITAL LOGIC FAMILIES*****6.1 INTRODUCTION**

1. Basically there are two types of semiconductor devices such as bipolar, unipolar, and based on these devices; integrated circuit (digital) have been made which are commercially available.

2. Various digital functions are being fabricated in a variety of form by using bipolar and unipolar technologies.

3. A group of (compatible IC's) with the same logic level and supply voltage for performing various logic families have been fabricated using a specific circuit configuration which is referred as logic family.

4. The various parameter or characteristics of digital IC's used to compare their performances are:

- | | |
|-----------------------------------|---------------------------------|
| (i) Speed of operation | (ii) Power dissipation |
| (iii) Figure of Merit | (iv) Fan out |
| (v) Current/voltage parameter | (vi) Noise Immunity |
| (vii) Operating Temperature Range | (viii) Power supply Requirement |
| (ix) Flexibilities Available | |

6.2 THERE ARE TWO TYPES OF LOGIC FAMILIES**1. Bipolar Logic Family****(i) Saturated**

- (a) RTL (Resistor Transistor Logic)
- (b) DCTL
- (c) I^2L
- (d) DTL
- (e) TTL
- (f) HTL

(ii) Unsaturated/Non-saturated

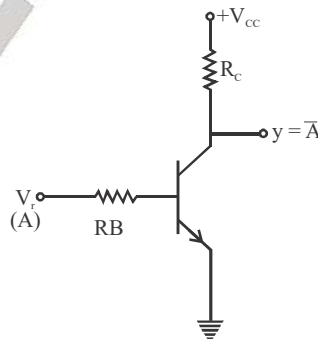
- (a) Schottky TTL
- (b) ECL (Emitter Coupled Logic)

2. Unipolar Logic Family

- (i) MOS: MOSFET are employed in MOS Logic
 - (a) NMOS
 - (b) PMOS
 - (c) CMOS (Complementary Metal Oxide Semiconductor)
 - (d) BiCMOS uses CMOS for input and logic operation and Bipolar Devices for output.

6.3 BASIC CONCEPTS OF LOGIC FAMILIES ANALYSES

Basic switching element:



SOLUTIONS

Sol 1. (a)

Sol 2. (a)

Sol 3. (a)

Sol 4. (c)

Sol 5. (c)

Sol 6. (c)

ECL circuits are non saturated logic circuits where transistors always operated under active and cutoff region. Hence it is the fastest logic among all the logic circuits.

Sol 7. (c)

Sol 8. (c)

Sol 9. (b)

In I^2L family, p-n-p and n-p-n transistors are integrated together due to this transistors will occupy less space hence density is more than any other logic family.

Sol 10. (c)

Figure of merit = $P_{disc} \times t_{pd} = mW \times ns = Pj$

Sol 11. (c)

Sol 12. (c)

Sol 13. (a)

Figure of merit = (Propagation delay time) \times (power dissipation)

Sol 14. (a)

Fan out of CMOS is high.

Sol 15. (c)

Trisate logic gates have three possible output states i.e., the logic '1' state, the logic '0' state and high-impedance state.

Sol 16. (a)

ECL gate has faster speed (2 ns propagation delay) of operation, than TTL (10 ns) and others. In ECL, the transistors are never in saturation, the input/output voltages have a small swing, the input impedance is high and output resistance is low, as a result, transistors charge states quickly.

Sol 17. (c)

Sol 18. (b)

CMOS-Lower power consumption.

Sol 19. (a)

I^2L -multiple collectors.

Sol 20. (d)

Totem pole refers to the output buffer.

Sol 21. (a)

Reason is the correct explanation of assertion.

Sol 22. (d)

CMOS has high input impedance and low output impedance.

Sol 23. (b)

It is also known as speed power product.

Sol 24. (c)

A. HTL-High Noise Immunity
B. CMOS-High Fanout
C. I^2L -Lowest product of power and delay
D. ECL-Highest speed of operation.

Sol 25. (d)

Sol 26. (c)

Sol 27. (a)

RTL does not have high switching speed.